



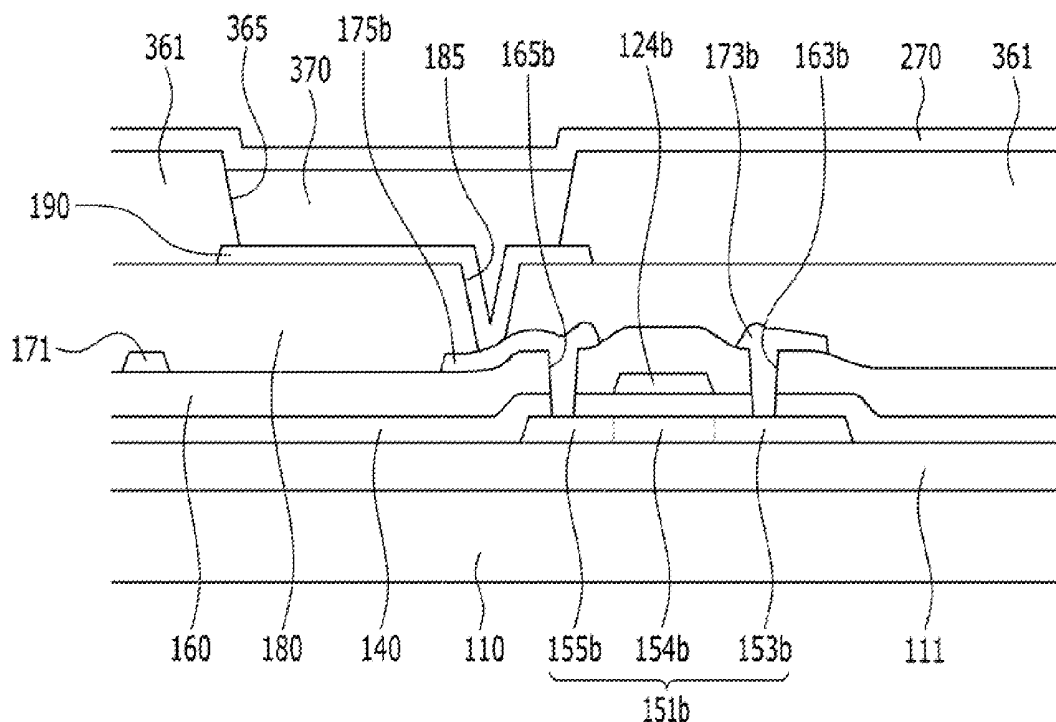
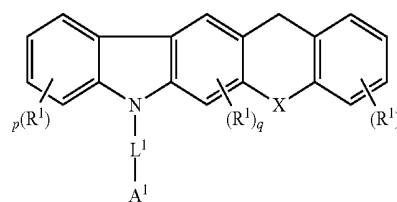
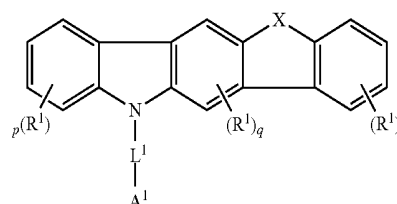
US 20160072077A1

(19) **United States**(12) **Patent Application Publication**
ITO et al.(10) **Pub. No.: US 2016/0072077 A1**(43) **Pub. Date: Mar. 10, 2016**(54) **ORGANIC LIGHT EMITTING DIODE AND
ORGANIC LIGHT EMITTING DISPLAY
DEVICE INCLUDING THE SAME***H01L51/0058* (2013.01); *C09K 11/025*
(2013.01); *H01L 51/0067* (2013.01); *H01L*
51/0071 (2013.01); *H01L 51/0077* (2013.01);
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Seoul (KR); **Jung Sub LEE**, Bucheon-si
(KR)(57) **ABSTRACT**

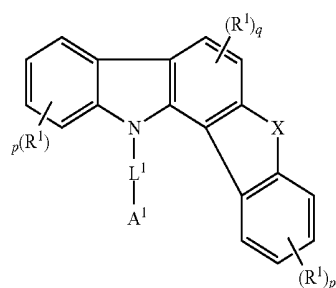
An organic light emitting element and an organic light emitting display, the organic light emitting element including a first compound represented by one of Chemical Formula 1-A to Chemical Formula 1-G, and a second compound represented by Chemical Formula 2:

(21) Appl. No.: **14/800,165**(22) Filed: **Jul. 15, 2015**(30) **Foreign Application Priority Data**

Sep. 4, 2014 (KR) 10-2014-0117616

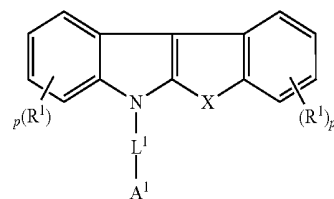
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H01L 51/00 (2006.01)
C09K 11/02 (2006.01)
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CPC *H01L 51/0072* (2013.01); *H01L 51/0081*
(2013.01); *H01L 27/3276* (2013.01);

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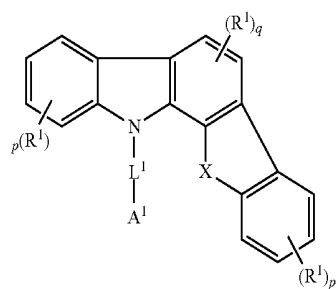
(1-C)

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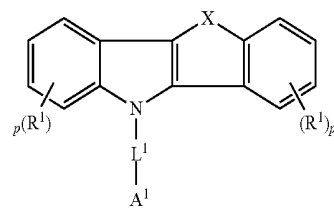


(1-F)

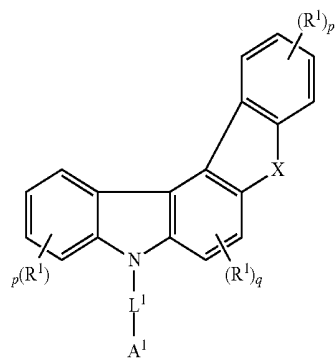
(1-D)



(1-G)



(1-E)



[Chemical Formula 2]

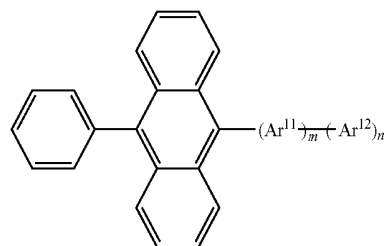


FIG. 1

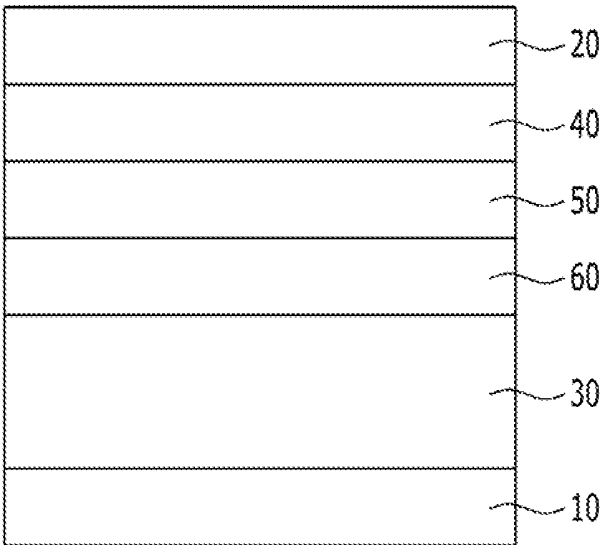


FIG. 2

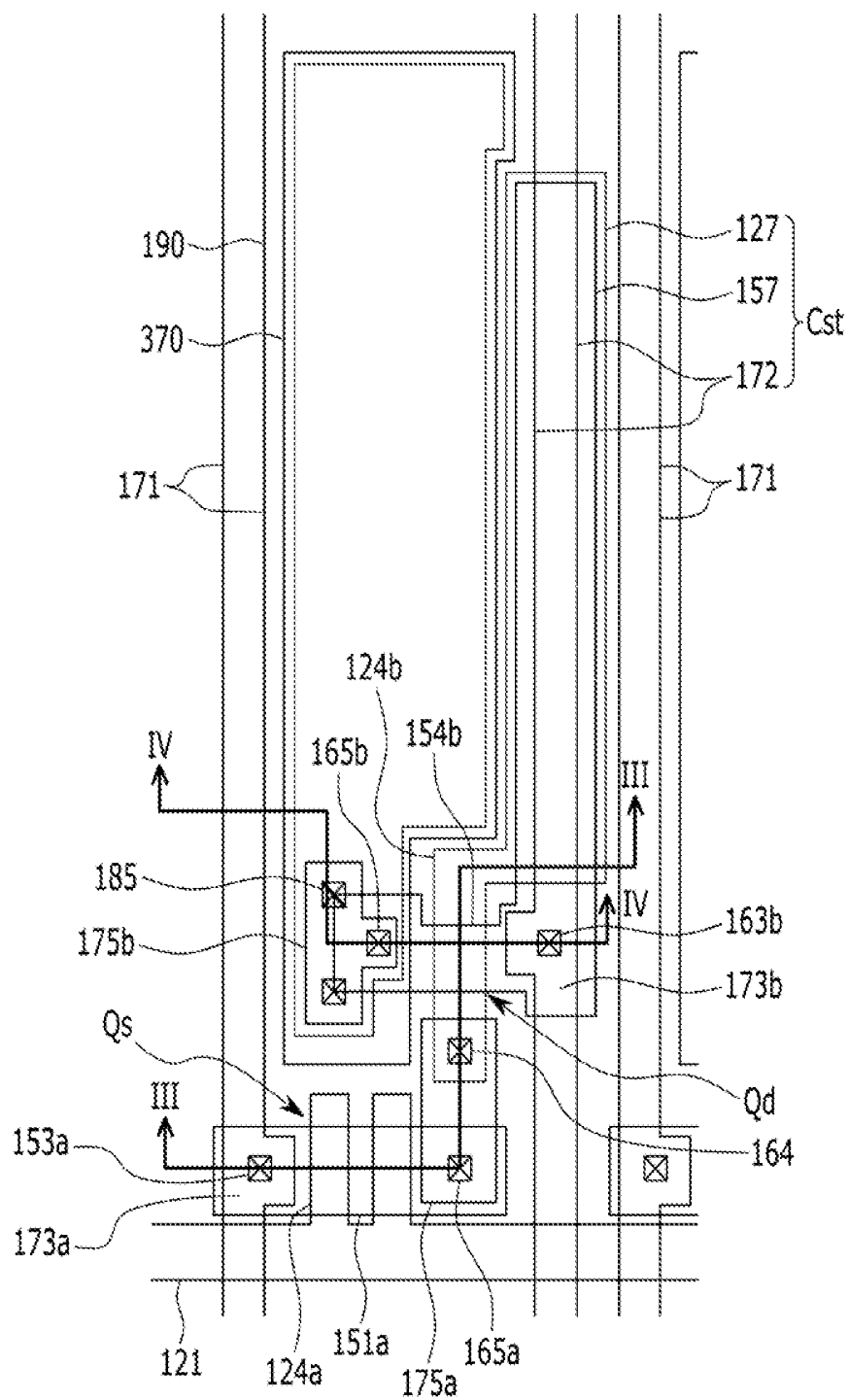


FIG. 3

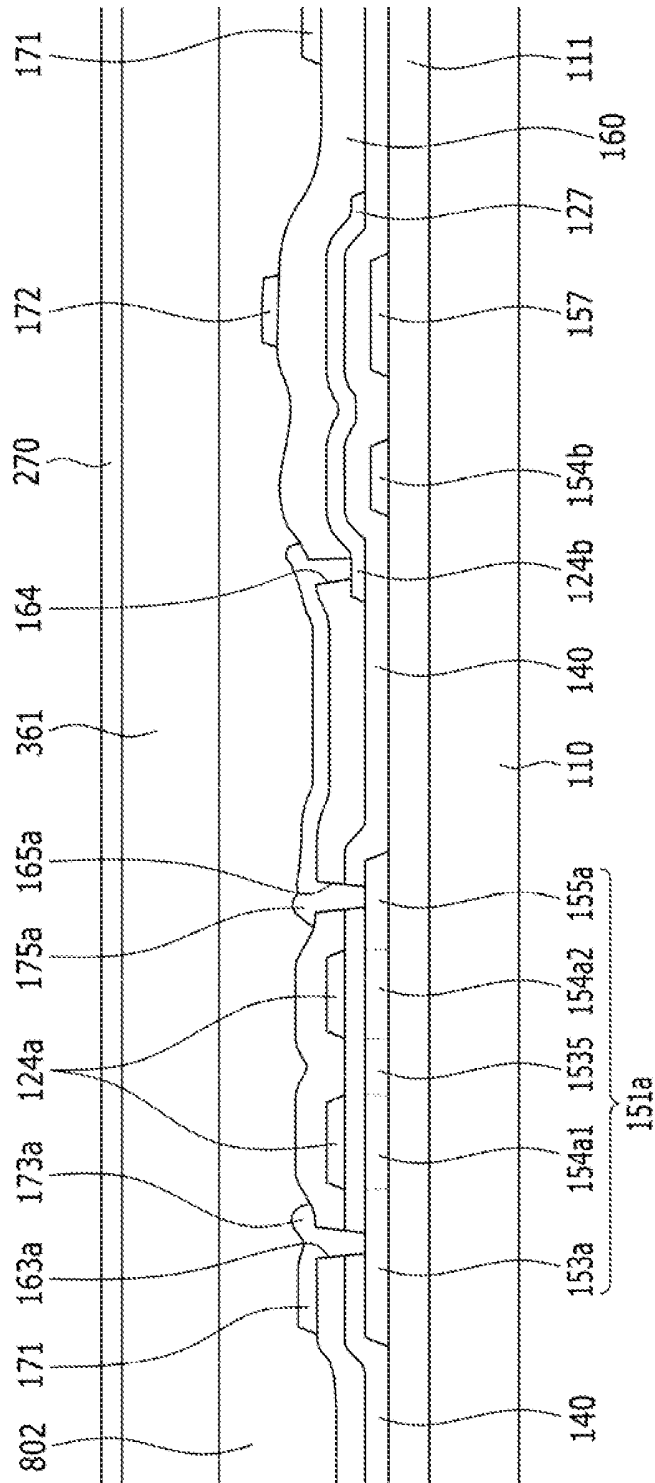
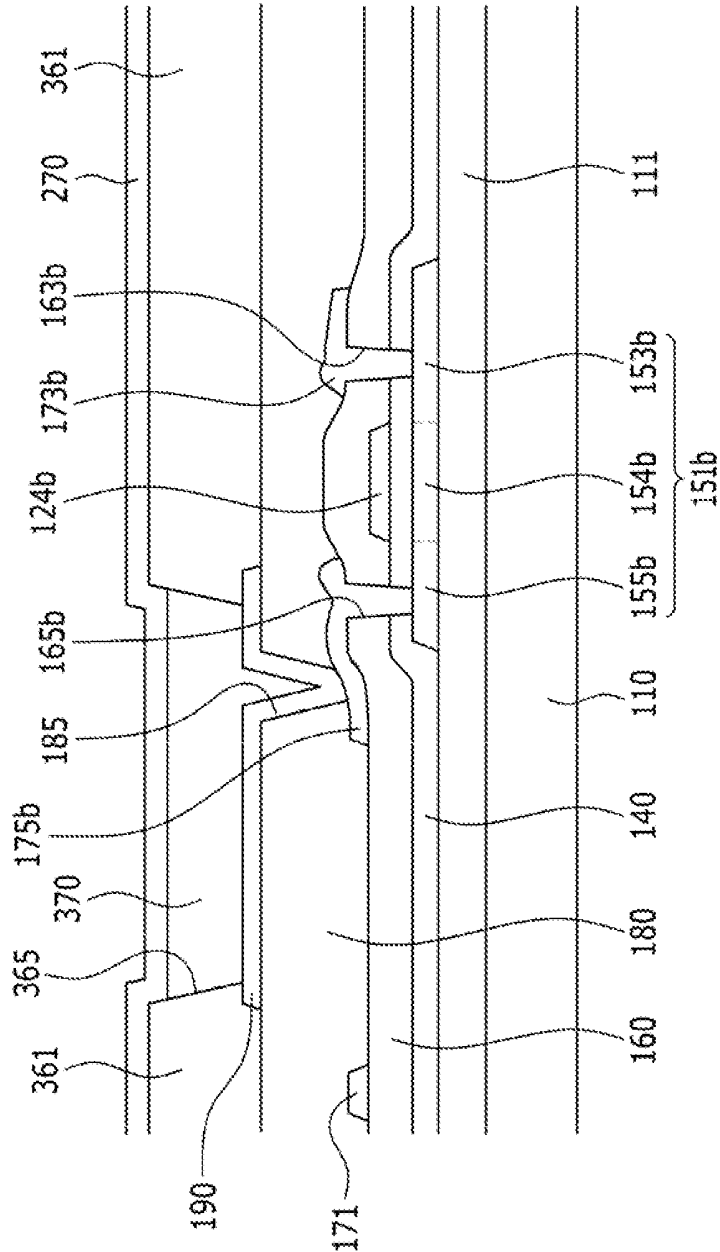


FIG. 4



ORGANIC LIGHT EMITTING DIODE AND ORGANIC LIGHT EMITTING DISPLAY DEVICE INCLUDING THE SAME

CROSS-REFERENCE TO RELATED APPLICATION

[0001] Korean Patent Application No. 10-2014-0117616, filed on Sep. 4, 2014, in the Korean Intellectual Property Office, and entitled: "Organic Light Emitting Diode and Organic Light Emitting Display Device Including the Same," is incorporated by reference herein in its entirety.

BACKGROUND

[0002] 1. Field

[0003] Embodiments relate to an organic light emitting element and an organic light emitting device including the same.

[0004] 2. Description of the Related Art

[0005] Recently, lightness and flatness of a monitor, a television, or the like have been demanded, and a cathode ray tube (CRT) has been substituted with a liquid crystal display (LCD) according to the demand. However, the liquid crystal display, which is a light receiving element, requires a separate backlight, and has a limitation in response speed, viewing angle, and the like.

[0006] An organic light emitting device, which is a self-emitting display element may have advantages of a wide viewing angle, excellent contrast, and a fast response time, and has greatly attracted attention.

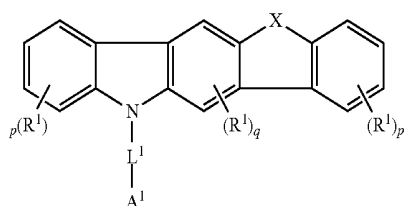
[0007] The organic light emitting device may include an organic light emitting element for light emission. The organic light emitting element may form excitons from combination of electrons injected from one electrode and holes injected from another electrode in an emission layer, and the excitons may emit energy such that light is emitted.

[0008] The above information disclosed in this Background section is only for enhancement of understanding of the background and therefore it may contain information that does not form the prior art that is already known in this country to a person of ordinary skill in the art.

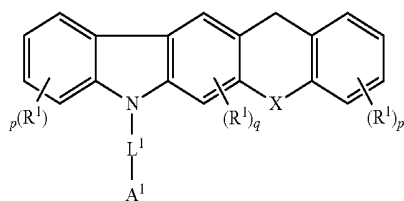
SUMMARY

[0009] Embodiments are directed to an organic light emitting element and an organic light emitting device including the same.

[0010] The embodiments may be realized by providing an organic light emitting element including a first compound represented by one of Chemical Formula 1-A to Chemical Formula 1-G, and a second compound represented by Chemical Formula 2:

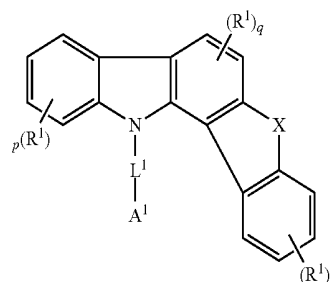


(1-A)

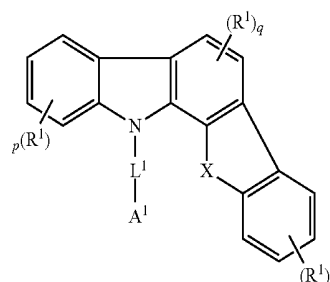


(1-B)

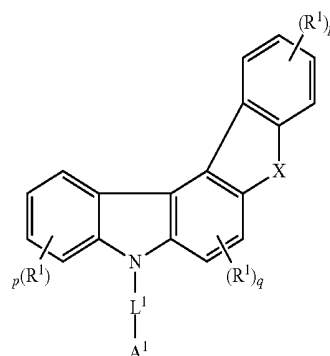
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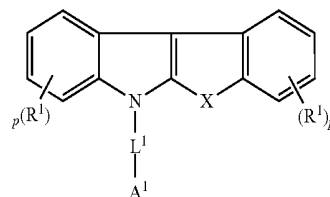
(1-C)



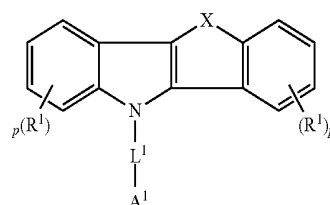
(1-D)



(1-E)



(1-F)

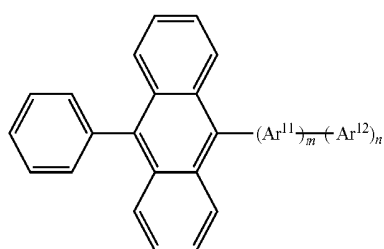


(1-G)

[0011] wherein, in Chemical Formula 1-A to Chemical Formula 1-G, A¹ is a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group or a substituted or unsubstituted ring-type C6 to C30 condensed aromatic heterocyclic group, L¹ is a single bond, a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group, a substituted or unsubstituted C6 to C30 condensed aromatic hydrocarbon group, a substituted or unsubstituted C2 to C30 aromatic heterocyclic group, or a substituted or unsubstituted C2 to C30 condensed aromatic heterocyclic group, X is S, O, N—R', or C(R¹)₂, each R¹ is independently hydrogen, fluorine, a cyano group, a

substituted or unsubstituted C1 to C20 alkyl group, a substituted or unsubstituted C1 to C20 alkoxy group, a substituted or unsubstituted C1 to C20 haloalkyl group, a substituted or unsubstituted C1 to C20 haloalkoxy group, a substituted or unsubstituted C1 to C10 alkylsilyl group, a substituted or unsubstituted C6 to C30 arylsilyl group, a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group, a substituted or unsubstituted C6 to C30 condensed aromatic hydrocarbon group, a substituted or unsubstituted C2 to C30 aromatic heterocyclic group, or a substituted or unsubstituted C2 to C30 condensed aromatic heterocyclic group, p is an integer of 1 to 4, q is an integer of 1 to 2,

[Chemical Formula 2]



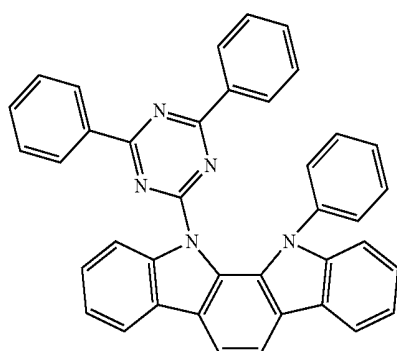
[0012] wherein, in Chemical Formula 2, each Ar^{11} is independently a substituted or unsubstituted C5 to C30 arylene group or a substituted or unsubstituted C5 to C30 heteroarylene group, m is an integer of 0 to 3, such that when m is 0, Ar^{11} is a single bond, each Ar^{12} is independently a substituted or unsubstituted C5 to C30 aryl group or a substituted or unsubstituted C5 to C30 heteroaryl group, and n is an integer of 1 to 3.

[0013] The organic light emitting element may include an anode and a cathode that face each other; an emission layer between the anode and the cathode; a hole transfer layer between the anode and the emission layer; an electron transfer layer between the cathode and the emission layer; and a hole blocking layer between the electron transfer layer and the emission layer, the hole blocking layer may include the first compound, and the emission layer may include the second compound.

[0014] Ar^{11} of the second compound may include a substituted or unsubstituted phenylene group or a substituted or unsubstituted naphthylene group.

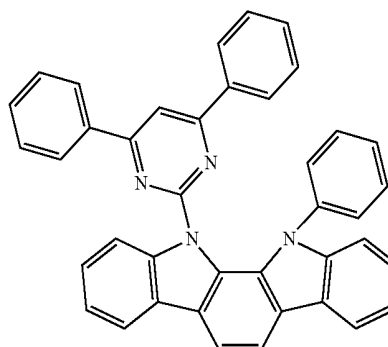
[0015] The first compound may be represented by one of the following Chemical Formula 1-1 to Chemical Formula 1-7:

(1-1)

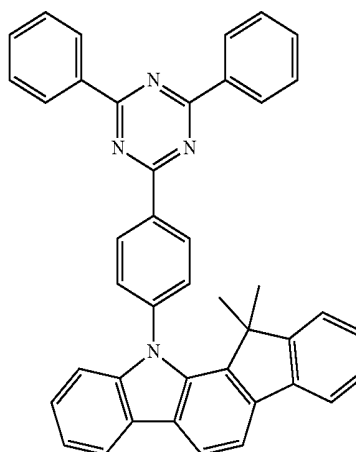


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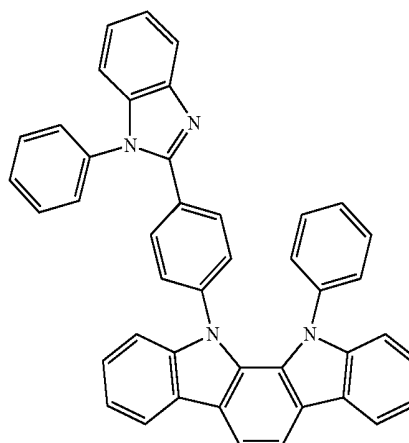
(1-2)



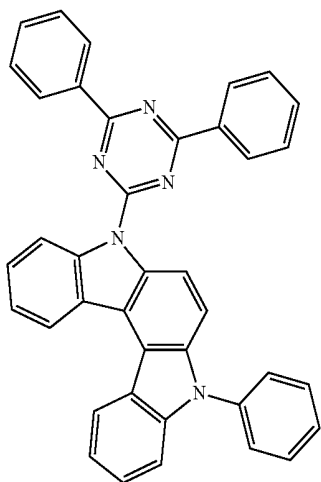
(1-3)



(1-4)



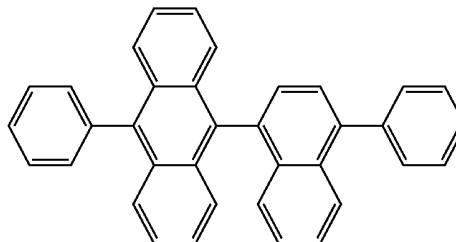
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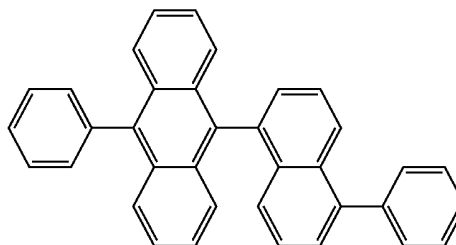
(1-5)

[0016] The second compound may be represented by one of the following Chemical Formula 2-1 to Chemical Formula 2-8:

(2-1)

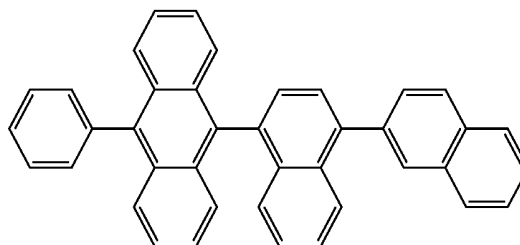


(2-2)

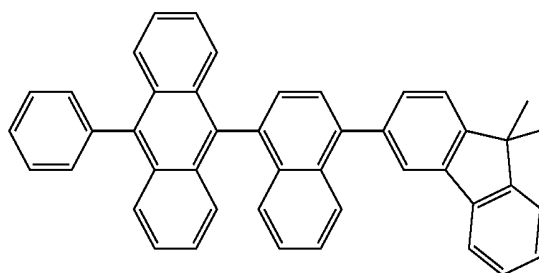


(1-6)

(2-3)

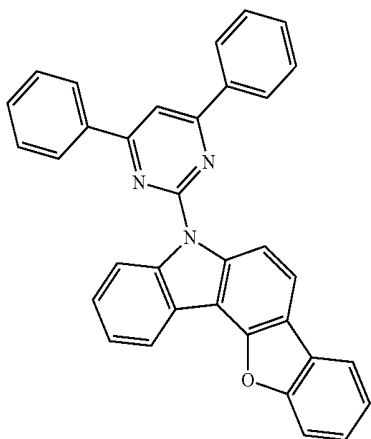
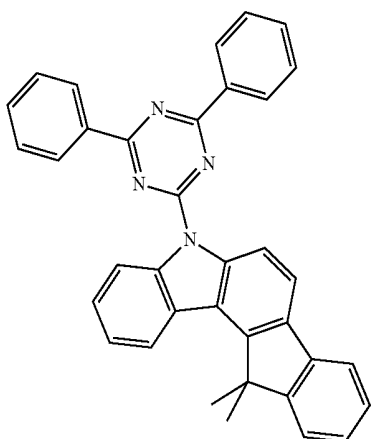
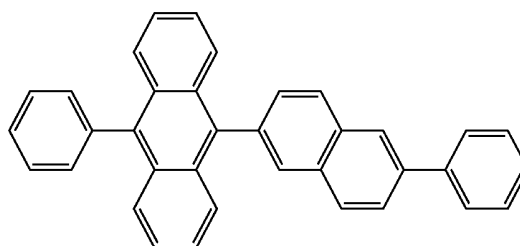


(2-4)



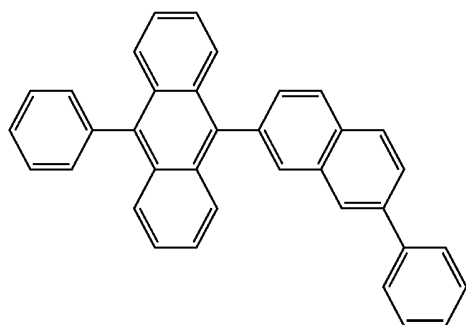
(1-7)

(2-5)

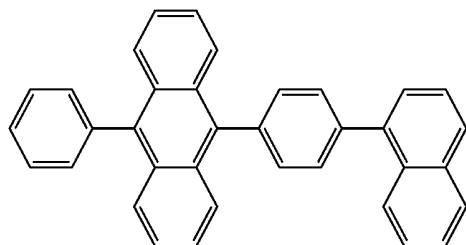


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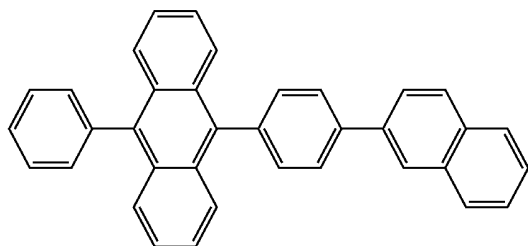
(2-6)



(2-7)



(2-8)

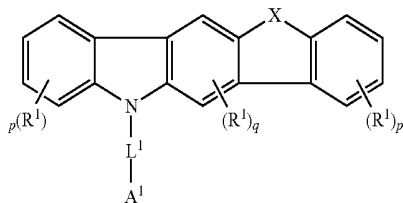


[0017] The electron transfer layer may include a metal or a metal complex.

[0018] The hole blocking layer may have a thickness of about 1 nm to about 100 nm.

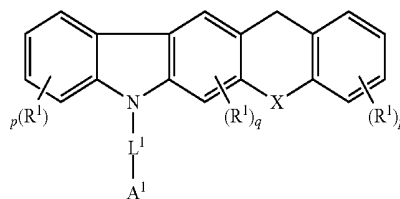
[0019] The embodiments may be realized by providing an organic light emitting display including a substrate; gate lines on the substrate; data lines and a driving voltage line crossing the gate lines; a switching thin film transistor connected with the gate line and the data line; a driving thin film transistor connected with the switching thin film transistor and the driving voltage line; and an organic light emitting element connected with the driving thin film transistor, wherein the organic light emitting element includes a first compound represented by one of Chemical Formula 1-A to Chemical Formula 1-G, and a second compound represented by Chemical Formula 2:

(1-A)

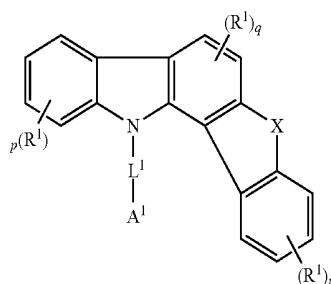


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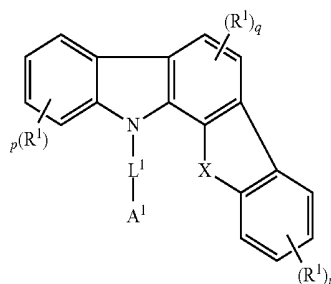
(1-B)



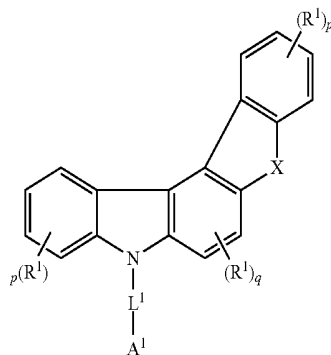
(1-C)



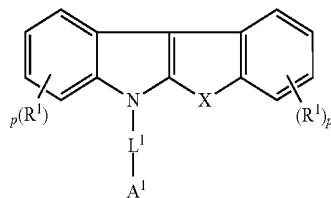
(1-D)



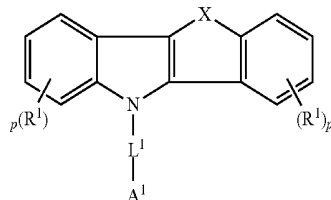
(1-E)



(1-F)

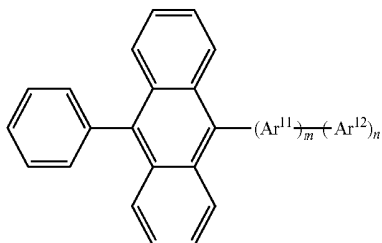


(1-G)



[0020] wherein, in Chemical Formula 1-A to Chemical Formula 1-G, A^1 is a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group or a substituted or unsubstituted C6 to C30 condensed aromatic heterocyclic group, L^1 is a single bond, a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group, a substituted or unsubstituted C6 to C30 condensed aromatic hydrocarbon group, a substituted or unsubstituted C2 to C30 aromatic heterocyclic group, or a substituted or unsubstituted C2 to C30 condensed aromatic heterocyclic group, X is S, O, N— R^1 , or C(R^1)₂, each R^1 is independently, hydrogen, fluorine, a cyano group, a substituted or unsubstituted C1 to C20 alkyl group, a substituted or unsubstituted C1 to C20 alkoxy group, a substituted or unsubstituted C1 to C20 haloalkyl group, a substituted or unsubstituted C1 to C20 haloalkoxy group, a substituted or unsubstituted C1 to C10 alkylsilyl group, a substituted or unsubstituted C6 to C30 arylsilyl group, a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group, a substituted or unsubstituted C2 to C30 aromatic heterocyclic group, or a substituted or unsubstituted C2 to C30 condensed aromatic heterocyclic group, p is an integer of 1 to 4, q is an integer of 1 to 2,

[Chemical Formula 2]

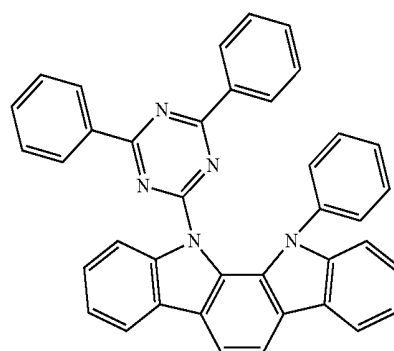


[0021] wherein, in Chemical Formula 2, each Ar^{11} is independently a substituted or unsubstituted C5 to C30 arylene group or a substituted or unsubstituted C5 to C30 heteroarylene group, m is an integer of 0 to 3, such that when m is 0, Ar^{11} is a single bond, each Ar^{12} is independently a substituted or unsubstituted C5 to C30 aryl group or a substituted or unsubstituted C5 to C30 heteroaryl group, and n is an integer of 1 to 3.

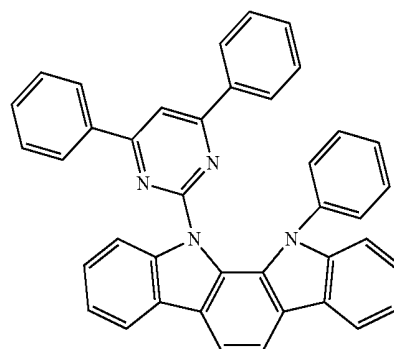
[0022] The organic light emitting element may include an anode and a cathode that face each other; an emission layer between the anode and the cathode; a hole transfer layer between the anode and the emission layer; an electron transfer layer between the cathode and the emission layer; and a hole blocking layer between the electron transfer layer and the emission layer, the hole blocking layer may include the first compound, and the emission layer may include the second compound.

[0023] Ar^{11} of the second compound may include a substituted or unsubstituted phenylene group or a substituted or unsubstituted naphthylene group.

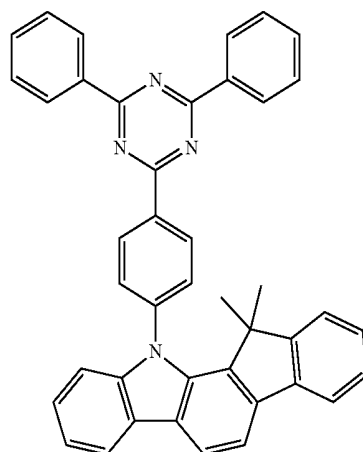
[0024] The first compound may be represented by one of the following Chemical Formula 1-1 to Chemical Formula 1-7:



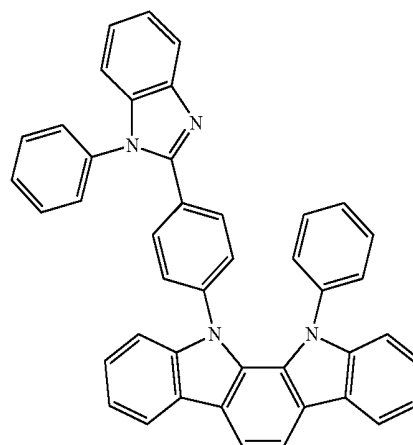
(1-1)



(1-2)

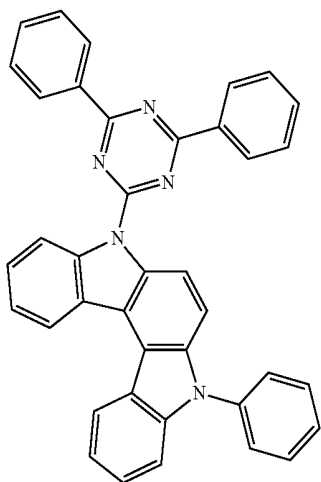


(1-3)



(1-4)

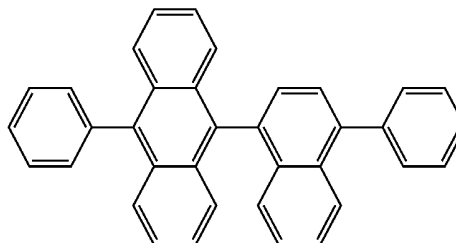
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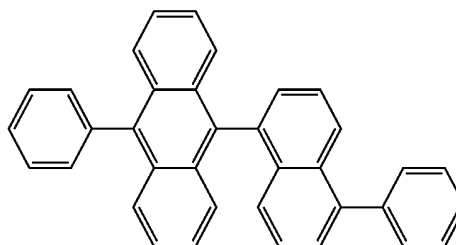
(1-5)

[0025] The second compound may be represented by one of the following Chemical Formula 2-1 to Chemical Formula 2-8:

(2-1)

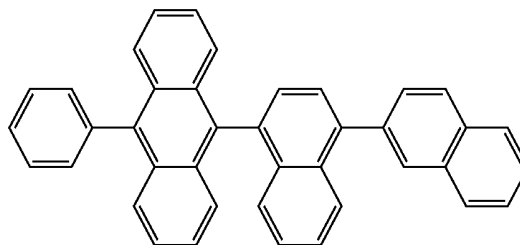


(2-2)

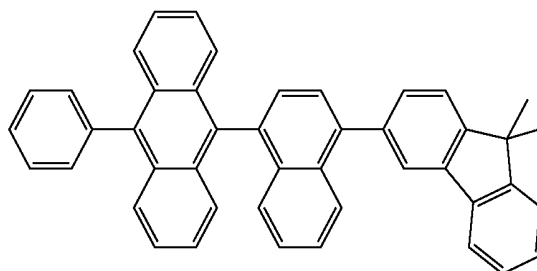


(1-6)

(2-3)

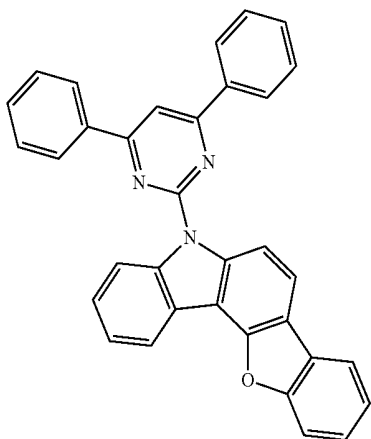
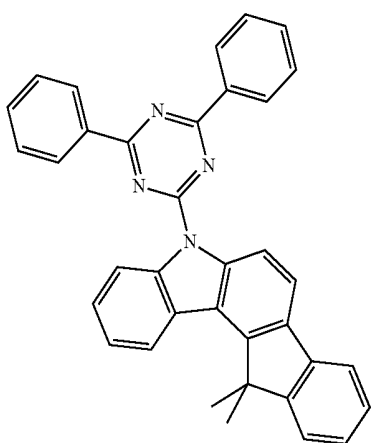
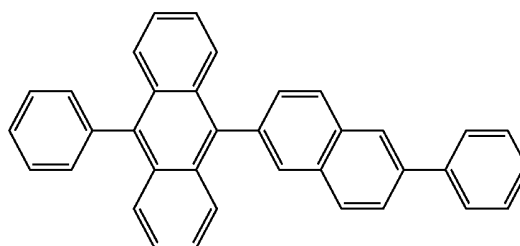


(2-4)



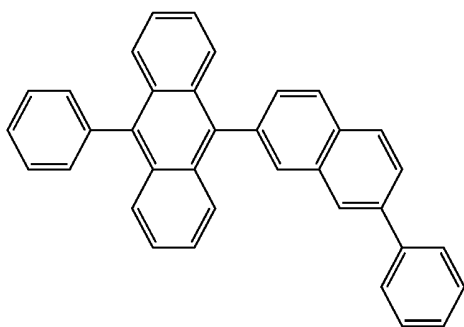
(1-7)

(2-5)

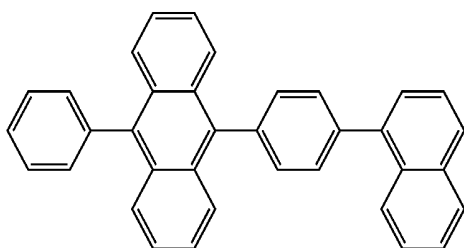


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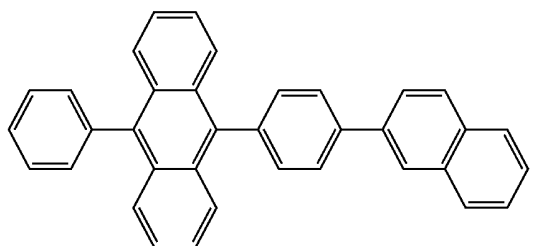
(2-6)



(2-7)



(2-8)



[0026] The electron transfer layer may include a metal or a metal complex.

[0027] The hole blocking layer may have a thickness of about 1 nm to about 100 nm.

BRIEF DESCRIPTION OF THE DRAWINGS

[0028] Features will be apparent to those of skill in the art by describing in detail exemplary embodiments with reference to the attached drawings in which:

[0029] FIG. 1 illustrates a structure of an organic light emitting element according to an exemplary embodiment.

[0030] FIG. 2 illustrates a layout view of an organic light emitting device according to the exemplary embodiment.

[0031] FIG. 3 illustrates a cross-sectional view of the organic light emitting device of FIG. 2, taken along the line III-III.

[0032] FIG. 4 illustrates a cross-sectional view of the organic light emitting device of FIG. 2, taken along the line IV-IV.

DETAILED DESCRIPTION

[0033] Example embodiments will now be described more fully hereinafter with reference to the accompanying drawings; however, they may be embodied in different forms and should not be construed as limited to the embodiments set forth herein. Rather, these embodiments are provided so that this disclosure will be thorough and complete, and will fully convey exemplary implementations to those skilled in the art.

[0034] In the drawing figures, the dimensions of layers and regions may be exaggerated for clarity of illustration. Like reference numerals refer to like elements throughout.

[0035] It will be understood that when an element such as a layer, film, region, or substrate is referred to as being “on” another element, it can be directly on the other element or intervening elements may also be present. In contrast, when an element is referred to as being “directly on” another element, there are no intervening elements present.

[0036] In the present specification, the term “substituted”, unless separately defined, means a substitution with a substituent selected from a group of deuterium, C1 to C6 alkyl groups, C6 to C36 aryl groups, C2 to C30 heteroaryl groups, C1 to C30 alkoxy groups, C2 to C30 alkenyl groups, C6 to C30 aryloxy groups, C3 to C30 silyloxy groups, C1 to C30 acyl groups, C2 to C30 acyloxy groups, C2 to C30 heteroacyloxy groups, C1 to C30 sulfonyl groups, C1 to C30 alkylthiol groups, C6 to C30 arylthiol groups, C1 to C30 heterocyclothiol groups, C1 to C30 phosphoric acid amide groups, C3 to C40 silyl groups, NR¹R² (here, R¹ and R² are respectively substituents selected from a group consisting of a hydrogen atom, C1 to C30 alkyl groups, and C6 to C30 aryl groups), a carboxylic acid group, a halogen group, a cyano group, a nitro group, an azo group, a fluorene group, and a hydroxyl group.

[0037] In addition, in the specification, the term “hetero”, unless separately defined, means a single functional group contains 1 to 3 heteroatoms selected from the group of B, N, O, S, P, Si, and P(=O), and carbon atoms as the remainder.

[0038] Further, among groups used in chemical formulae of the present specification, definition of a representative group is as follows. (The number of carbons that limits substituents is not restrictive, and does not limit characteristics of the constituents).

[0039] An unsubstituted C1 to C30 alkyl group may be a linear type or a branched type, and nonrestrictive examples of the unsubstituted C1 to C30 alkyl group may include methyl, ethyl, propyl, iso-propyl, sec-butyl, hexyl, iso-amyl, hexyl, heptyl, octyl, nonyl, dodecyl, and the like.

[0040] An unsubstituted C1 to C30 alkoxy group indicates a group having a structure of —OA (wherein A is an unsubstituted C1 to C30 alkyl group as described above). Non-limiting examples of the unsubstituted C1 to C30 alkoxy group may include a methoxy group, an ethoxy group, a propoxy group, an isopropoxy group, a butoxy group, and a pentoxy group.

[0041] An unsubstituted C6 to C30 aryl group indicates a carbocyclic aromatic system containing at least one ring. At least two rings may be fused to each other or linked to each other by a single bond. The term “aryl” refers to an aromatic system, such as phenyl, naphthyl, or anthracenyl. Examples of the unsubstituted C6 to C30 aryl group may include a phenyl group, a tolyl group, a biphenyl group, a naphthyl group, an anthracenyl group, a terphenyl group, a fluorenyl group, a phenanthrenyl group, a pyrenyl group, a diphenylanthracenyl group, a diphenylanthracenyl group, a dinaphthylanthracenyl group, a pentacenyl group, a bromophenyl group, a hydroxyphenyl group, a stilbene group, an azobenzene group, and a ferrocenyl group.

[0042] An unsubstituted C2 to C30 heteroaryl group includes one, two, or three heteroatoms selected from a group consisting of B, N, O, S, P, Si, and P(=O). At least two rings may be fused to each other or linked to each other by a single bond. Examples of the unsubstituted C2 to C30 heteroaryl group may include a pyrazolyl group, an imidazolyl group, an oxazolyl group, a thiazolyl group, a triazolyl group, a tetrazolyl group, an oxadiazolyl group, a thiadiazolyl group, a

pyridinyl group, a triazinyl group, a carbazole group, an N-phenylcarbazole group, an indole group, a quinolyl group, an isoquinolyl group, a thiophene group, a dibenzothiophene group, and a dibenzimidazole group.

[0043] Hereinafter, an organic light emitting element according to an exemplary embodiment will be described in further detail. FIG. 1 illustrates a cross-sectional view of an organic light emitting element according to an exemplary embodiment.

[0044] Referring to FIG. 1, the organic light emitting element according to the exemplary embodiment may include an anode 10, a cathode 20 facing the anode 10, an emission layer 60 between the anode 10 and the cathode 20, a hole transport layer 30 between the anode 10 and the emission layer 60, an electron transport layer 40 between the cathode 20 and the emission layer 60, and a hole blocking layer 50 between the electron transport layer 40 and the emission layer 60.

[0045] A substrate (not shown) may be provided on a side of the anode 10 or on a side of the cathode 20. The substrate may be made of, e.g., an inorganic material such as glass, an organic material such as a polycarbonate, polymethylmethacrylate, polyethylene terephthalate, polyethylene naphthalate, a polyamide, polyether sulfone, or a combination thereof, or of a silicon wafer.

[0046] The anode 10 may be a transparent electrode or an opaque electrode. The transparent electrode may be, e.g., made of a conductive oxide such as indium tin oxide (ITO), indium zinc oxide (IZO), tin oxide (SnO_2), or a combination thereof, or a metal such as aluminum, silver, or magnesium with a thin thickness. The opaque electrode may be made of a metal, e.g., aluminum, silver, magnesium, or the like.

[0047] In an implementation, the anode 10 of the organic light emitting element according to the exemplary embodiment may have a structure in which a reflective layer is made of silver (Ag), aluminum (Al), chromium (Cr), molybdenum (Mo), tungsten (W), titanium (Ti), gold (Au), palladium (Pd), or an alloy film thereof, and an electrical reflective layer made of a transparent electrode material such as ITO, IZO, or ZnO, are layered.

[0048] The anode 10 may be formed using, e.g., a sputtering method, a vapor phase deposition method, an ion beam deposition method, an electron beam deposition method, or a laser ablation method.

[0049] The cathode 20 may include a material having a small work function for easy electron injection. For example, the material may be a metal such as magnesium, calcium, sodium, potassium, titanium, indium, yttrium, lithium, gadolinium, aluminum, silver, tin, lead, cesium, barium, or the like, or an alloy thereof, or a multi-layered structure material such as LiF/Al , LiO_2/Al , LiF/Ca , LiF/Al , and BaF_2/Ca . In an implementation, a metallic electrode such as aluminum may be used as the cathode 20.

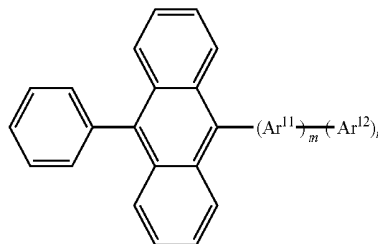
[0050] For example, the conductive material used as the cathode 20 according to the exemplary embodiment may include magnesium, calcium, tin, lead, titanium, yttrium, lithium, ruthenium, manganese, indium, aluminum, lithium fluoride, and the like, or an alloy thereof. The alloy may include magnesium/silver, magnesium/indium, lithium/aluminum, or the like. An alloy ratio of the alloys may be controlled based on a temperature of a deposition source, an atmosphere, a degree of vacuum, or the like, and an appropriate alloy ratio may be selected.

[0051] The anode 10 and the cathode 20 may be formed of two or more layers as desired.

[0052] The emission layer 60 may include a blue, red, or green emission material. In an implementation, the emission layer 60 may include a host and a dopant.

[0053] In an implementation, the emission layer 60 may include a second compound represented by Chemical Formula 2, below, as a host.

[Chemical Formula 2]



[0054] In Chemical Formula 2,

[0055] Ar^{11} may be or may include, e.g., a substituted or unsubstituted C5 to C30 arylene group or a substituted or unsubstituted C5 to C30 heteroarylene group. In an implementation, Ar^{11} may be or may include, e.g., a substituted or unsubstituted C6 to C30 arylene group or a substituted or unsubstituted C5 to C30 heteroarylene group. In an implementation, each Ar^{11} may independently be or may independently include, e.g., a substituted or unsubstituted C6 to C30 arylene group or a substituted or unsubstituted C5 to C30 heteroarylene group.

[0056] m may be an integer of 0 to 3. When m is 0, Ar^{11} may be a single bond. For example, a single bond may replace Ar^{11} .

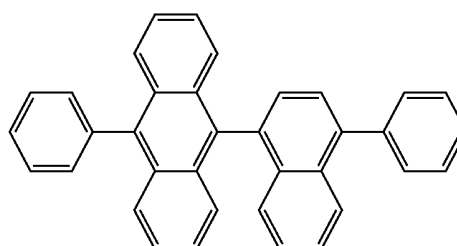
[0057] Ar^{12} may be or may include, e.g., a substituted or unsubstituted C5 to C30 aryl group or a substituted or unsubstituted C5 to C30 heteroaryl group. In an implementation, Ar^{12} may be or may include, e.g., a substituted or unsubstituted C6 to C30 aryl group or a substituted or unsubstituted C5 to C30 heteroaryl group. In an implementation, each Ar^{12} may independently be or may independently include, e.g., a substituted or unsubstituted C6 to C30 aryl group or a substituted or unsubstituted C5 to C30 heteroaryl group.

[0058] n may be an integer of 1 to 3. When m or n is 2 or more, the Ar^{11} and Ar^{12} may be the same as or different from one another.

[0059] In an implementation, the compound represented by Chemical Formula 2 may be represented by one of the following Chemical Formula 2-1 to Chemical Formula 2-97.

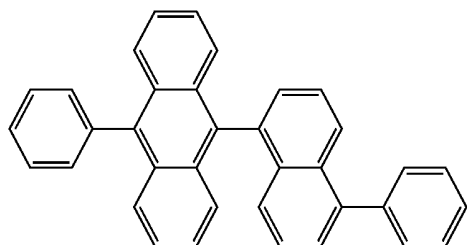
[Chemical Formula 2-1 to Chemical Formula 2-8]

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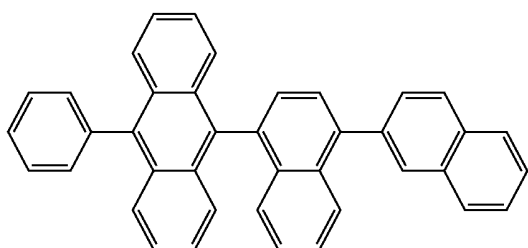


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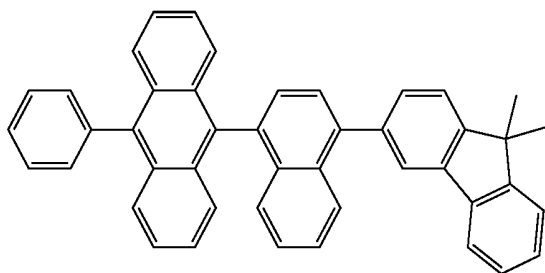
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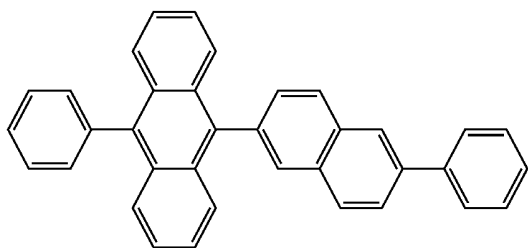
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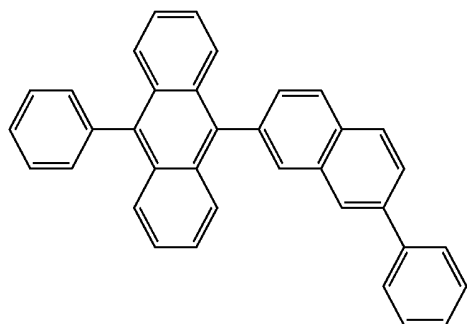
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(2-5)

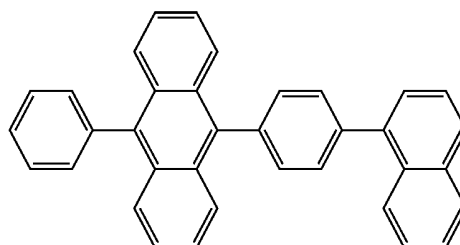


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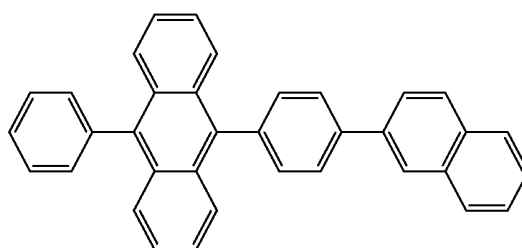


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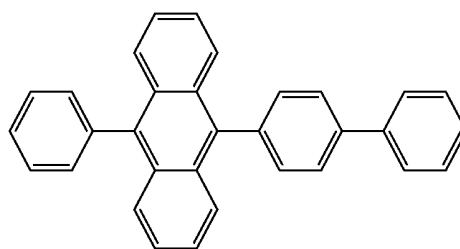


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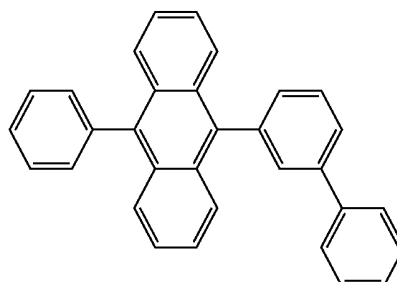


[Chemical Formula 2-9 to Chemical Formula 2-30]

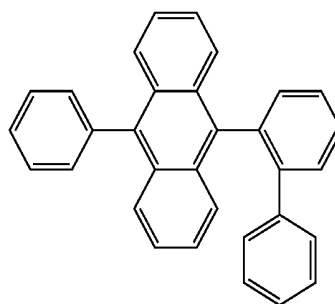
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(2-10)

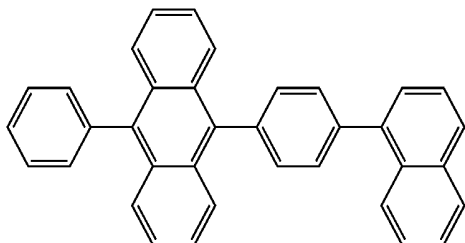


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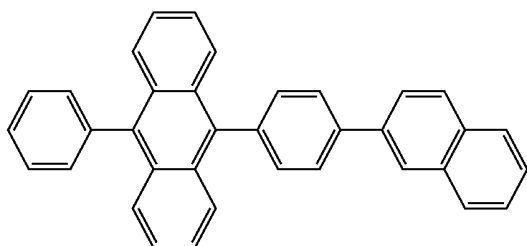


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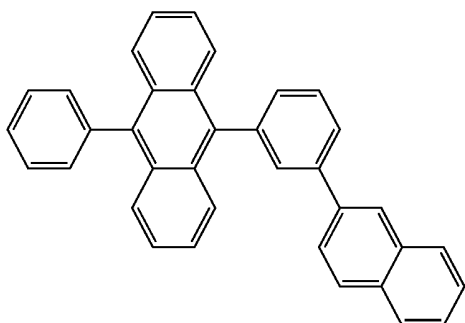
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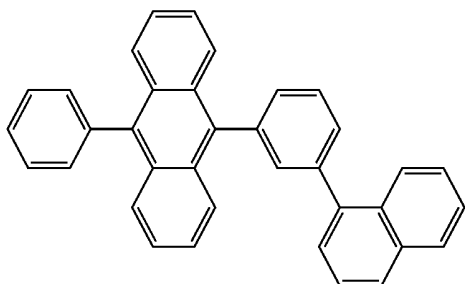
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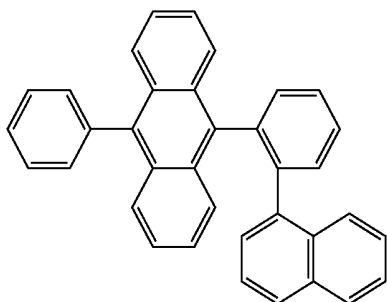
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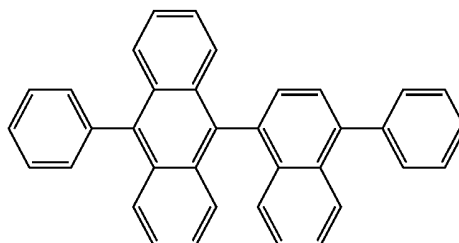


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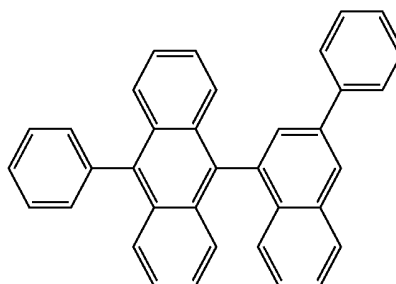


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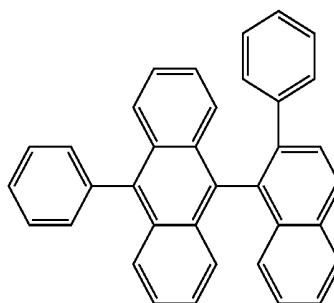
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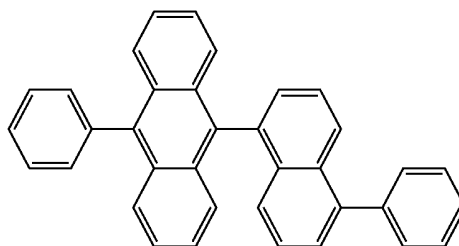
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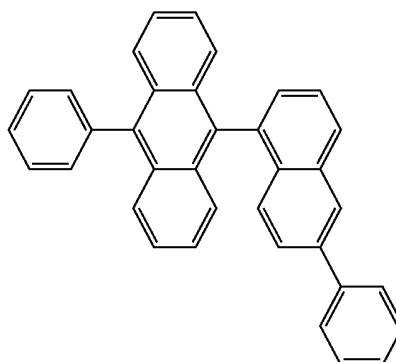
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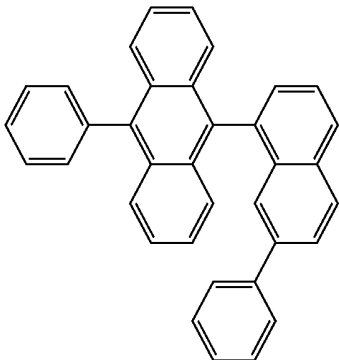


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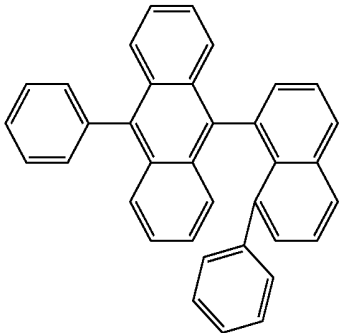


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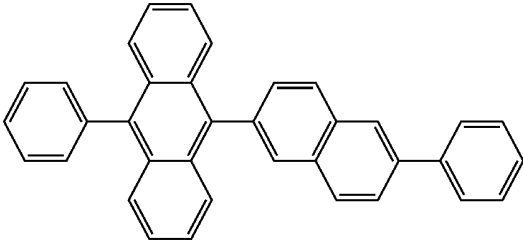
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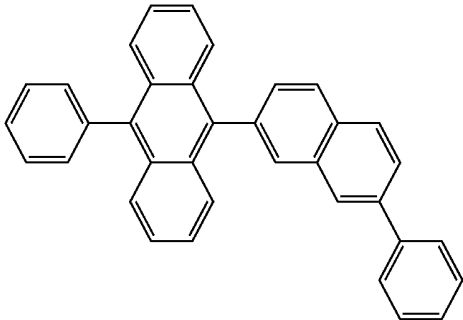
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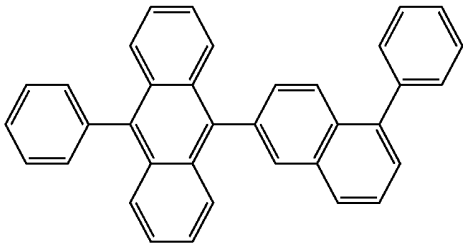
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(2-25)

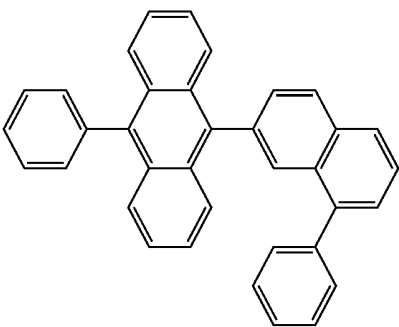


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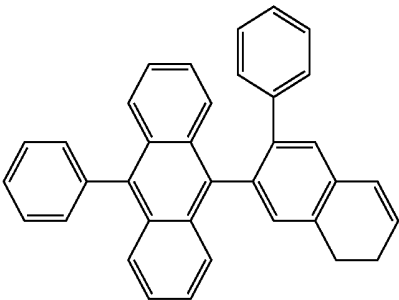


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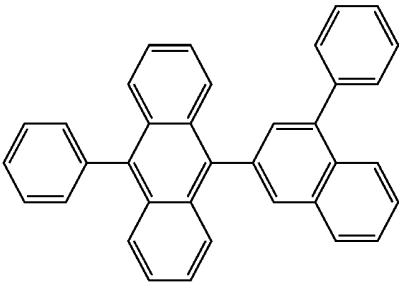
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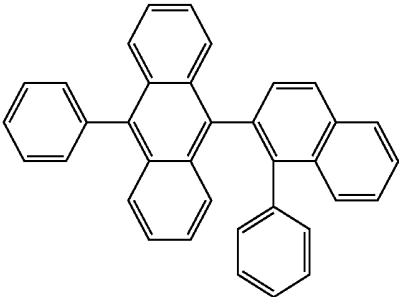
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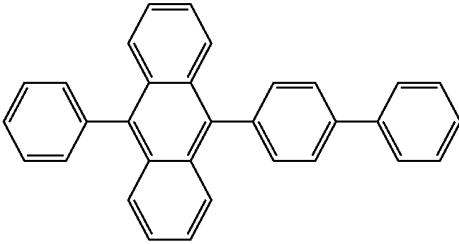


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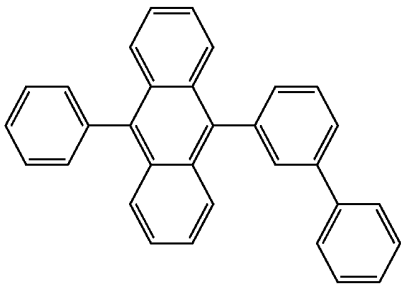
[Chemical Formula 2-31 to Chemical Formula 2-52]

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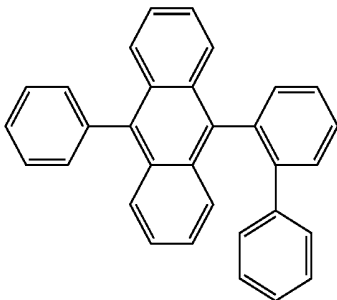


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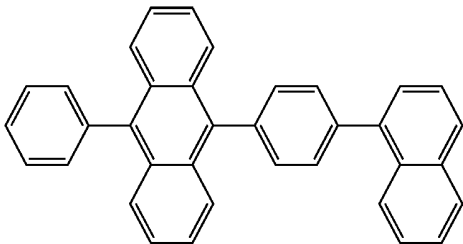
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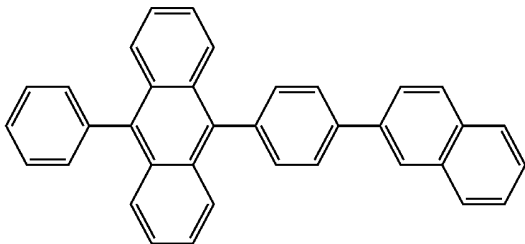
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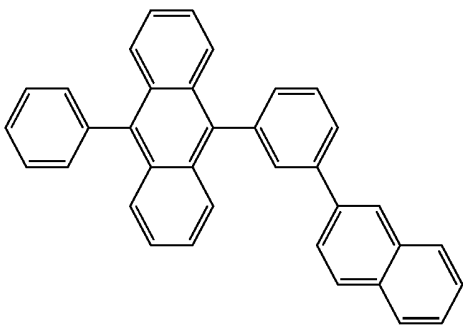
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(2-35)

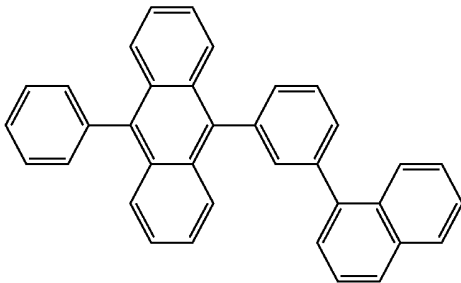


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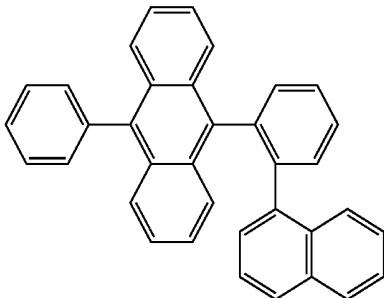


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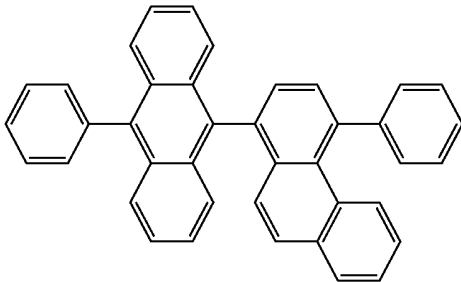
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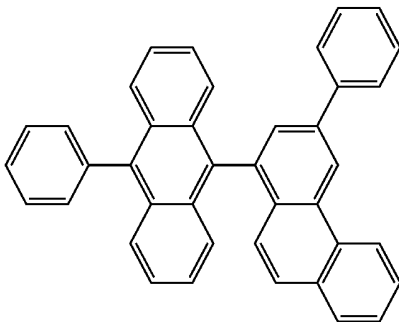
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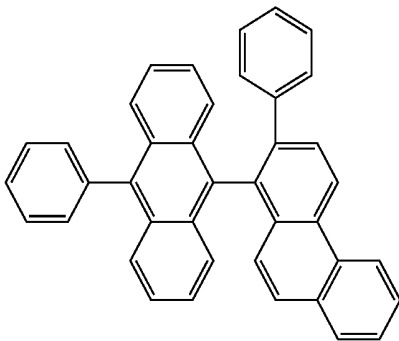
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(2-40)

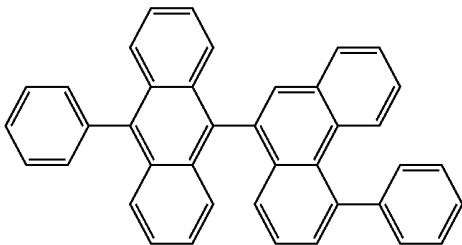


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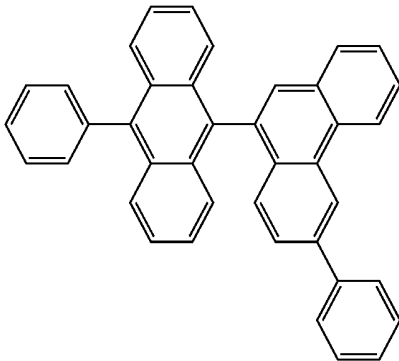


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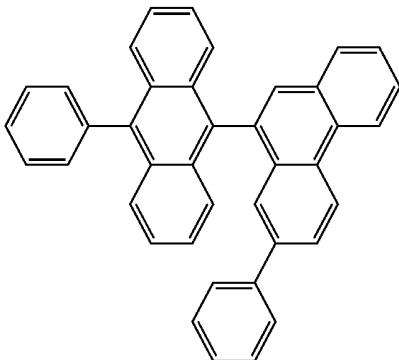
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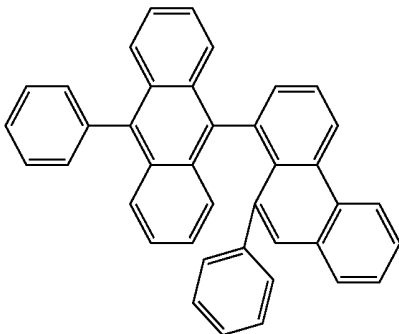
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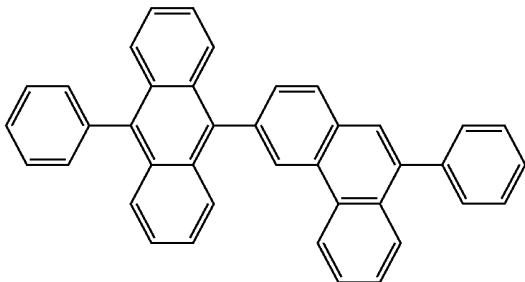
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(2-45)

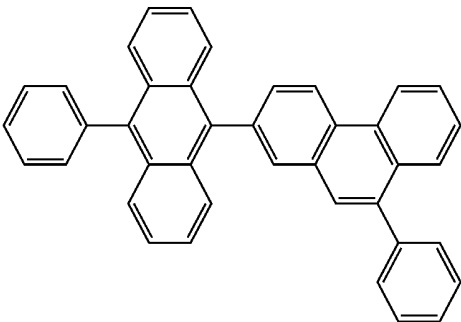


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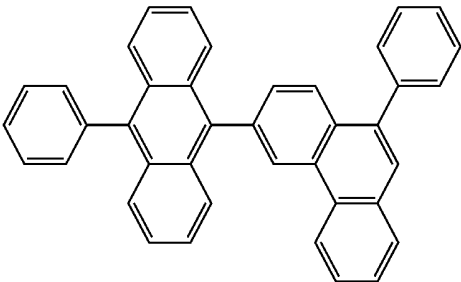


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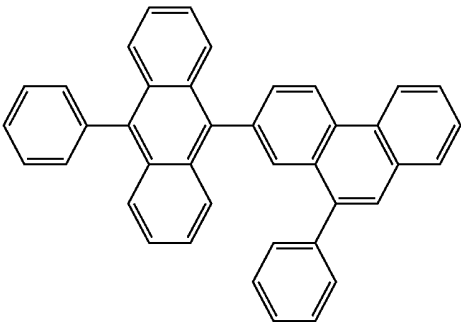
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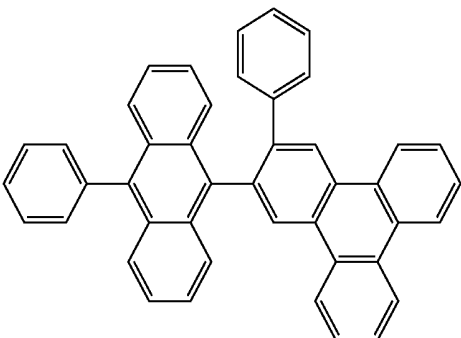
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(2-49)

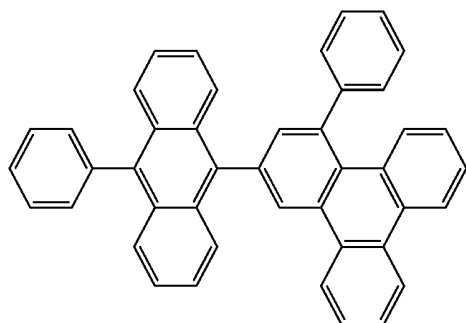


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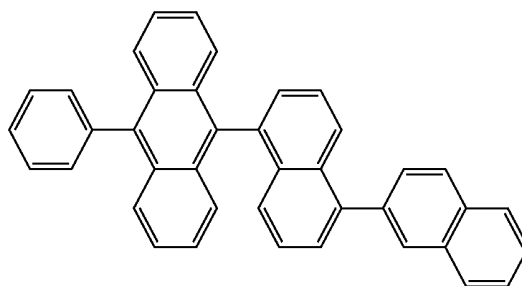
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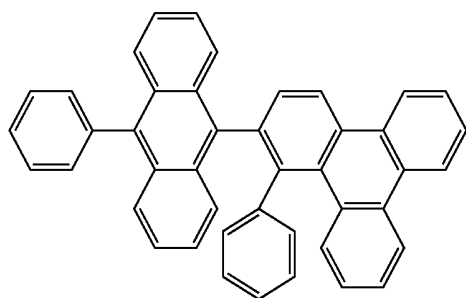
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(2-56)

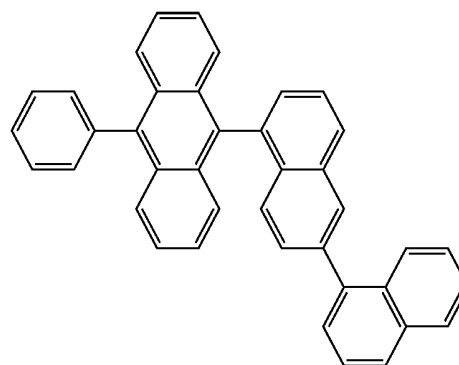


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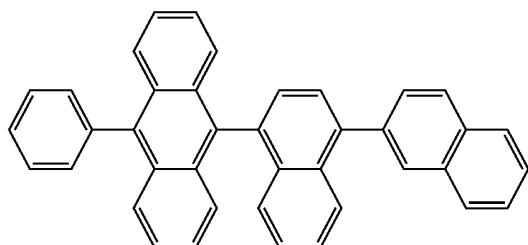


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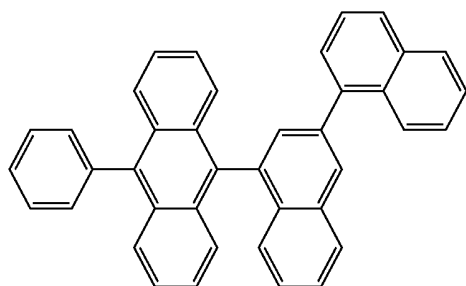
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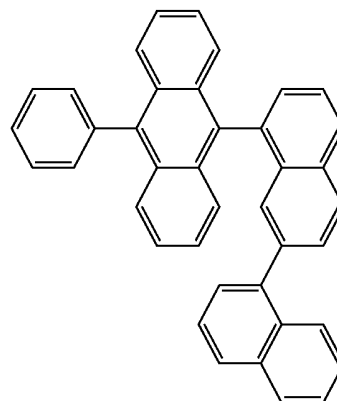
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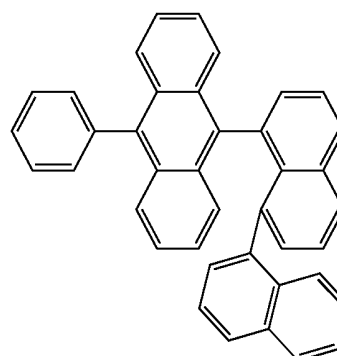
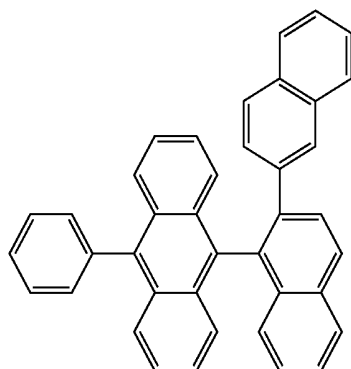
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(2-55)

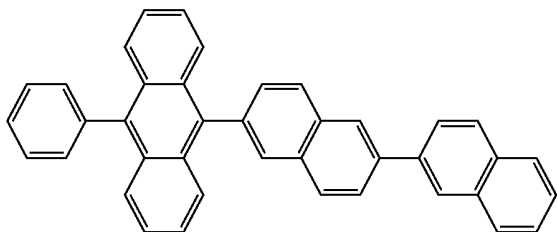


(2-59)

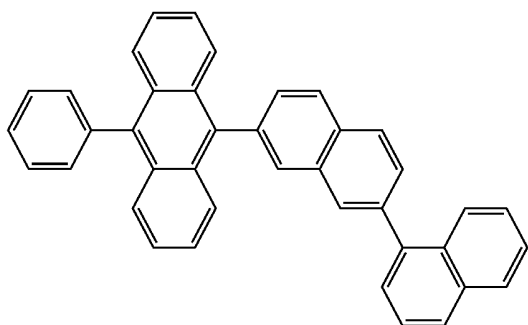


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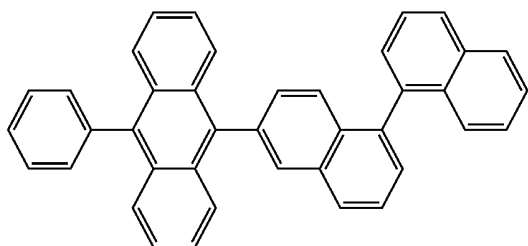
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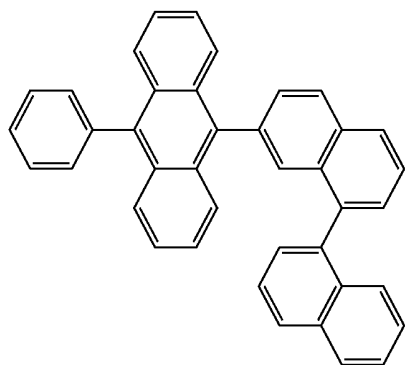
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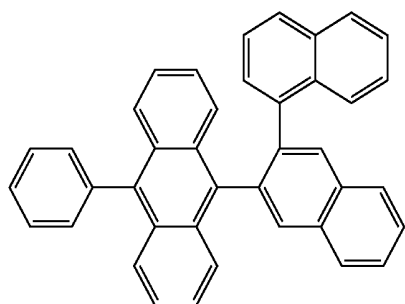
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(2-63)

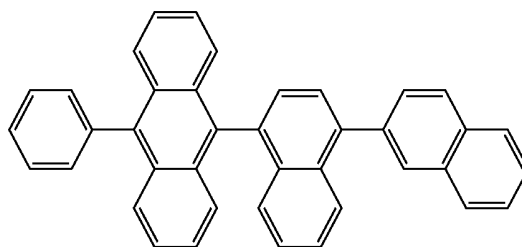


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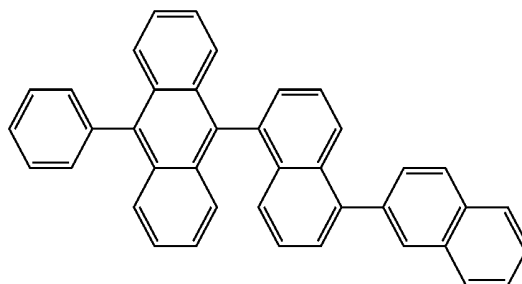


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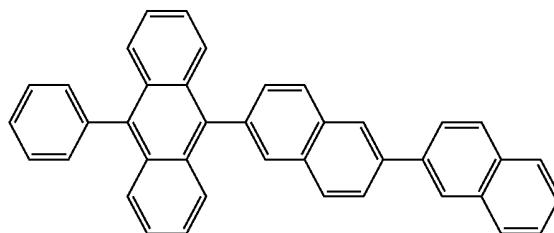
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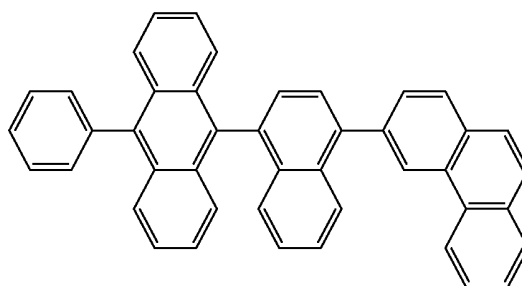
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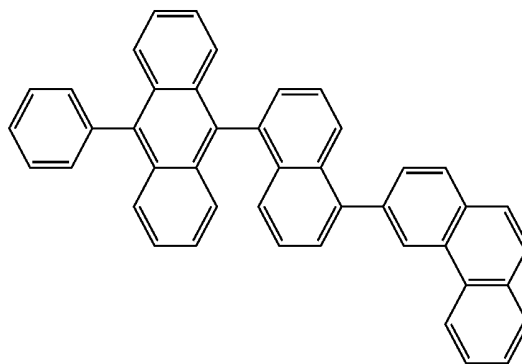
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(2-68)

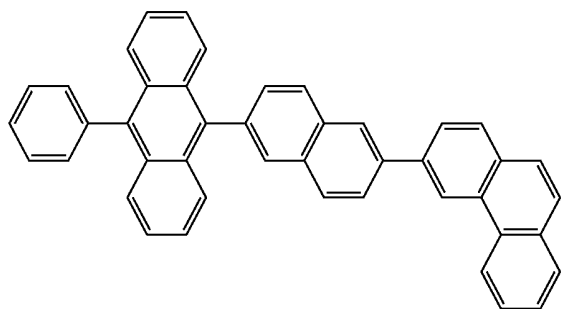


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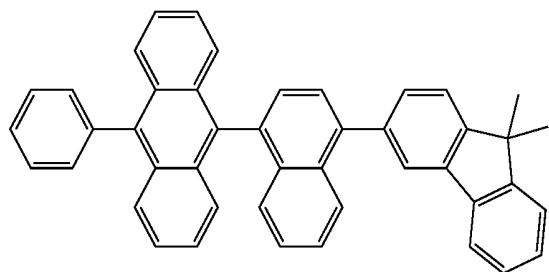


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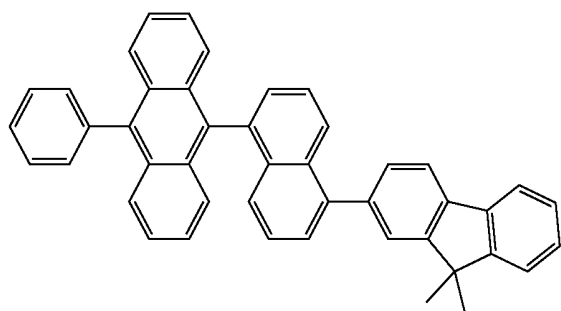
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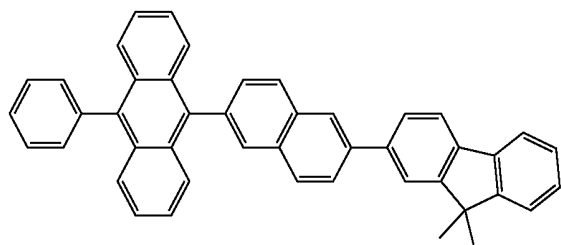
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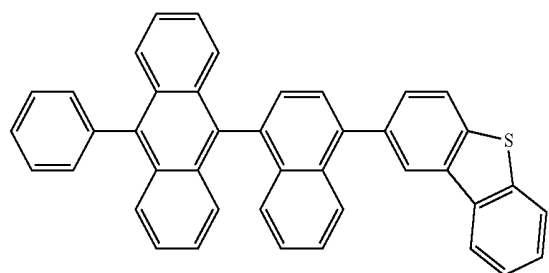
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(2-73)

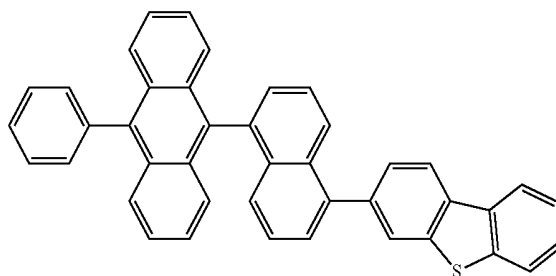


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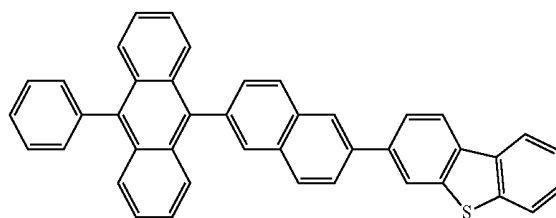


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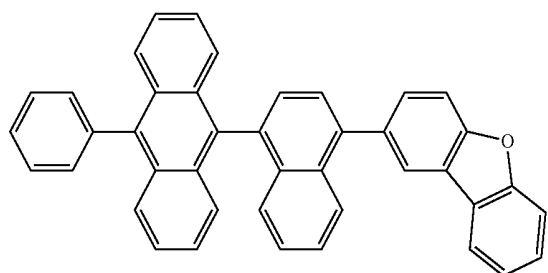
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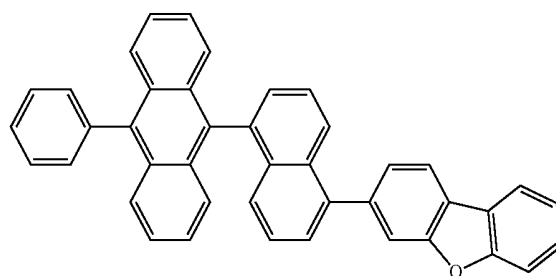
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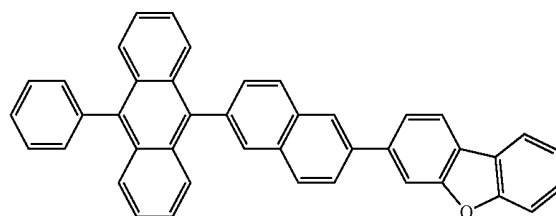
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(2-78)



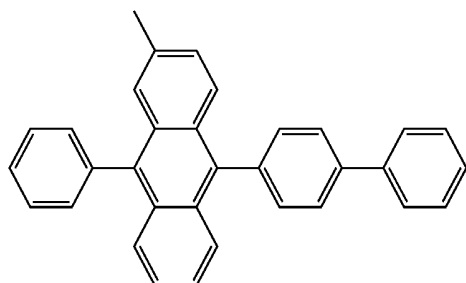
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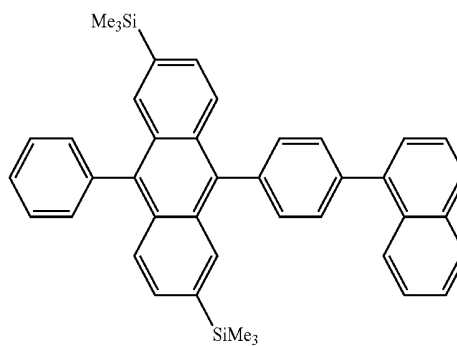
[Chemical Formula 2-80 to Chemical Formula 2-97]

(2-80)

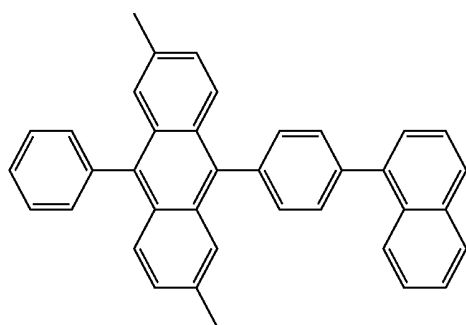


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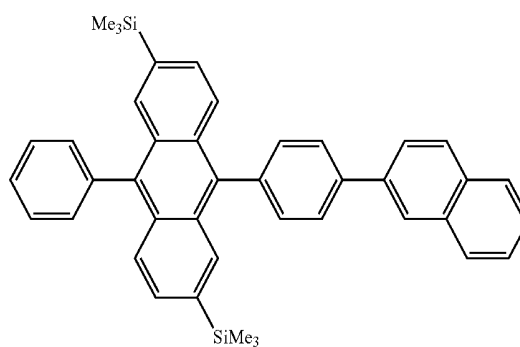
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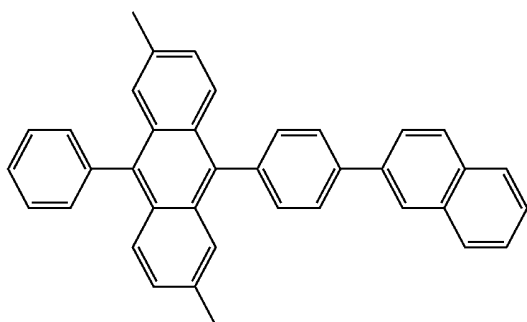
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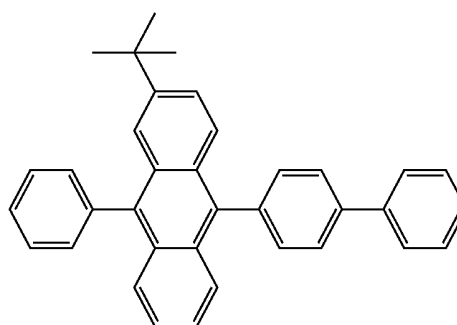
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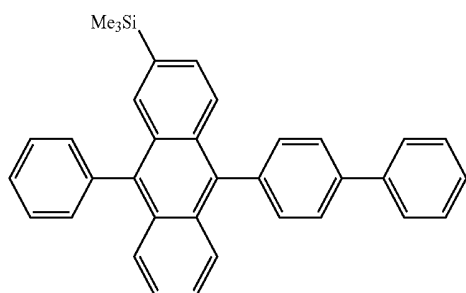
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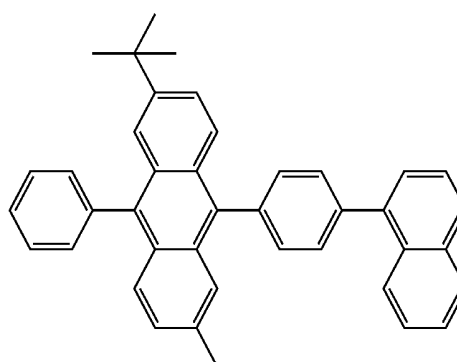
(2-86)



(2-83)

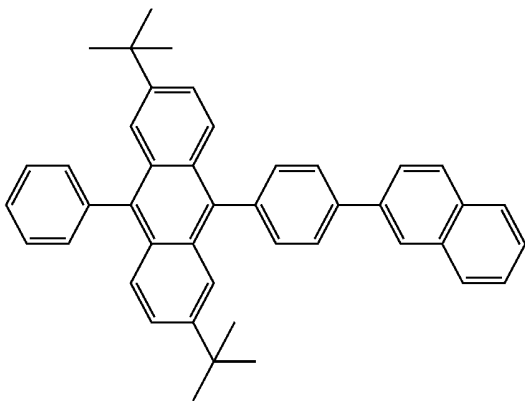


(2-87)



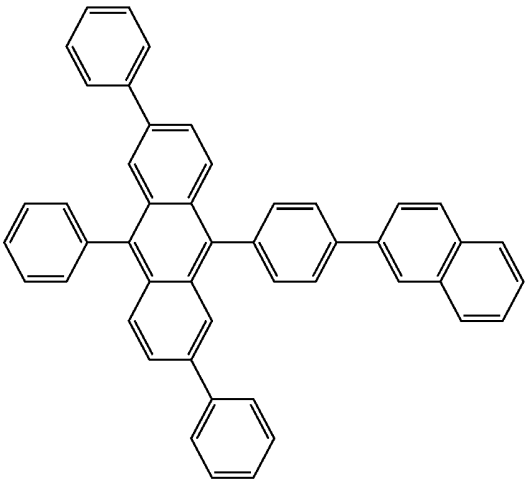
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(2-88)



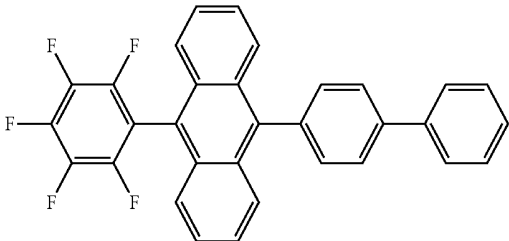
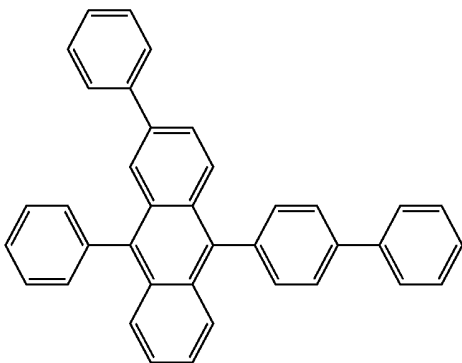
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(2-91)



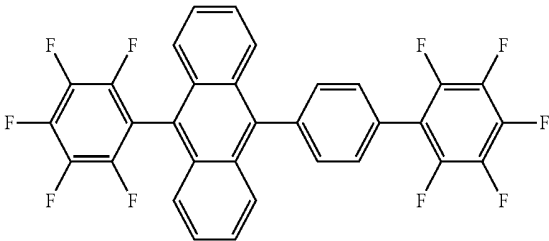
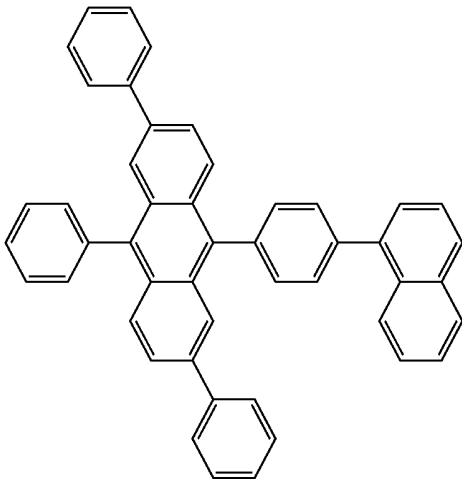
(2-92)

(2-89)



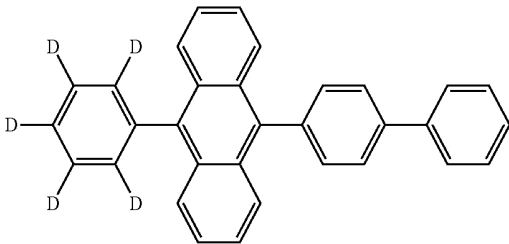
(2-93)

(2-90)



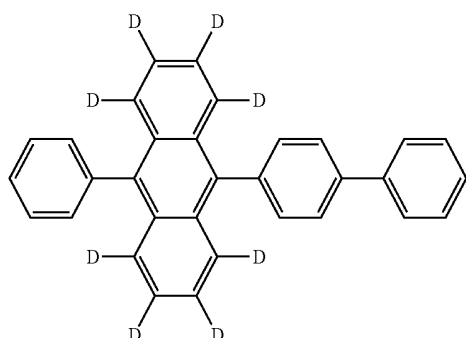
(2-94)

(2-95)

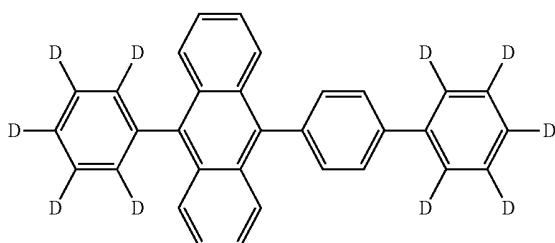


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(2-96)



(2-97)



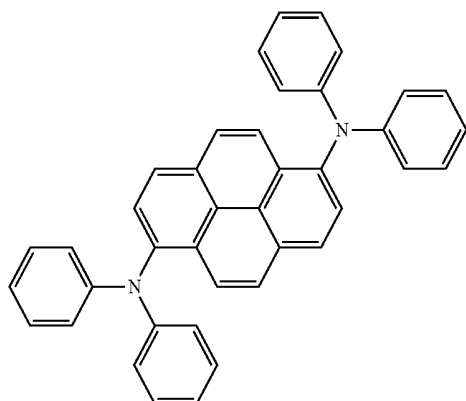
[0060] The emission layer **60** may additionally include a dopant material. For the dopant material, IDE102 and IDE105 (which may be purchased from Idemitsu Co., Ltd.) and C545T (which may be purchased from Hayashibara Co., Ltd.) may be used as a fluorescent dopant, and a red phosphorous dopant PtOEP, RD 61 of UDC Co., Ltd, a green phosphorous dopant Ir(ppy)₃(py=2-phenylpyridine), a blue phosphorous dopant F₂Irpic, and a red phosphorous dopant RD 61 of UDC Co., Ltd. may be used as a phosphorous dopant.

[0061] In an implementation, as a dopant of the emission layer **60**, Ir(ppy)₃, Ir(ppy)₂acac, (piq)₂Ir(acac), Pt(OEP), or the like may be used.

[0062] In an implementation, the dopant may be included in an amount of about 0.01 to about 15 parts by weight, based on 100 parts by weight of the host.

[0063] In an implementation, the dopant may include a third compound represented by Chemical Formula 3.

[Chemical Formula 3]



[0064] The third compound may be included in an amount of about 1 to about 10 parts by weight, based on 100 parts by weight of the host.

[0065] The third compound may be included in an amount of about 5 wt % or less in the emission layer **60**, e.g., based on a total weight of the emission layer **60**.

[0066] The second compound and the third compound may be deposited simultaneously when forming the emission layer.

[0067] The emission layer **60** may be formed using various methods, e.g., a vacuum deposition method, a spin coating method, a casting method, an LB method, or the like.

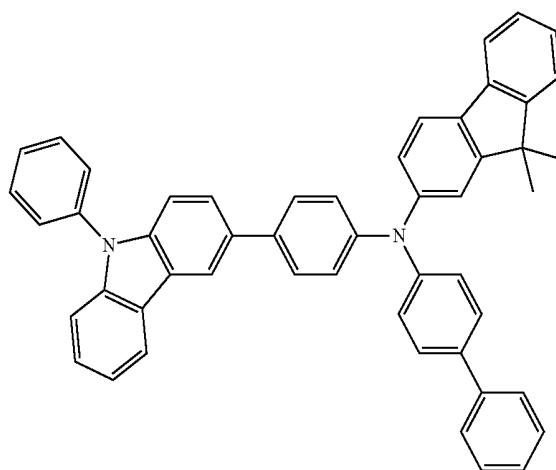
[0068] When an organic layer, e.g., the emission layer **60**, is formed using the vacuum deposition method, the deposition conditions may vary according to the material that is used to form the organic layer, and the structure and thermal characteristics of the organic layer. For example, the deposition conditions may include a deposition temperature of about 100° C. to 500° C., a vacuum pressure of about 10⁻⁸ to about 10⁻³ torr, and/or a deposition speed of about 0.01 to about 100 Å/s.

[0069] When an organic layer, e.g., the emission layer **60**, is formed using the spin coating method, the coating conditions may vary according to the material used to form the organic layer, and the structure and thermal characteristics of the organic layer. For example, the coating conditions may include a coating speed of about 2,000 rpm to about 5,000 rpm, and/or a thermal treatment temperature of about 80° C. to about 200° C. at which the solvent remaining after coating may be removed.

[0070] The hole transfer layer **30** may include a suitable hole transfer material, e.g., an arylene-diamine derivative, a starburst-based compound, a biphenyl-diamine derivative including a spiro group, and a ladder-type compound. In an implementation, the hole transfer layer **30** may include, e.g., a carbazole derivate including 4,4',4'''-tris[(3-methylphenyl(phenyl)amino)]triphenylamine (m-MTDATA), 1,3,5-tris[4-(3-methylphenylphenylamine)phenyl]benzene (m-MT-DATB), copper phthalocyanine (CuPc), N-phenylcarbazole, polyvinyl carbazole, or the like, and/or a suitable amine derivate including an aromatic condensed ring such as N,N'-bis(3-methylphenyl)-N,N'-diphenyl-[1,1-biphenyl]-4,4'-diamine (TPD), N,N'-di(naphthalene-1-yl)-N,N'-diphenyl benzidine (α-NPD), or the like.

[0071] In an implementation, the hole transport layer may include a fifth compound represented by Chemical Formula 5.

[Chemical Formula 5]



[0072] The hole transfer layer 30 may have a thickness of about 50 Å to about 1,000 Å, e.g., about 100 Å to about 600 Å. When the thickness of the hole transfer layer 30 satisfies the above-stated range, an excellent hole transfer characteristic may be acquired without a substantial increase of a driving voltage.

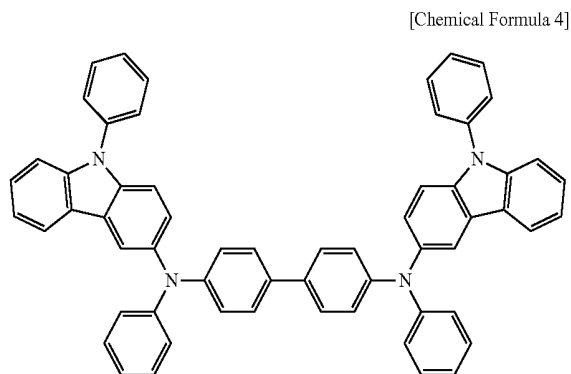
[0073] The hole transfer layer 30 may further include an assistant or auxiliary material for improvement of film conductivity. For example, the auxiliary material may be evenly or unevenly dispersed in the layers or may be variously deformed.

[0074] The hole transport layer 30 may be formed on an upper portion of the anode 10 using various methods, e.g., a vacuum deposition method, a spin coating method, a casting method, an LB method, or the like. When the vacuum deposition method and/or the spin coating method are used to form the hole transport layer 30, deposition conditions and coating conditions may vary according to a compound that is used to form the hole transport layer 30.

[0075] An electron blocking layer (not shown) may be additionally provided between the hole transfer layer 30 and the emission layer 60. In an implementation, a hole injection layer (not shown), which is a material that facilitates injection of holes from the anode, may be layered between the hole transfer layer 30 and the anode 10.

[0076] As the hole injection material, a suitable hole injection material such as TCTA, m-MTDATA, m-MTDAPB, Pani/DBSA (Polyaniline/Dodecylbenzene sulfonic acid), which is a soluble conductive polymer, or PEDOT/PSS (Poly(3,4-ethylenedioxythiophene)/Poly(4-styrenesulfonate): poly(3,4-ethylenedioxythiophene)/poly(4-styrenesulfonate)), Pani/CSA (Polyaniline/Camphor sulfonic acid), or PANI/PSS (Polyaniline)/Poly(4-styrenesulfonate)) may be used.

[0077] In an implementation, the hole injection layer may include a fourth compound represented by Chemical Formula 4.



[0078] The hole injection layer may be formed using various methods, e.g., a vacuum deposition method, a spin coating method, a casting method, an LB method, or the like. When the hole injection layer is formed using the vacuum deposition method, the deposition conditions may vary according to the material that is used to form the hole injection layer, and the structure and thermal characteristics of the hole injection layer. For example, the deposition conditions may include a deposition temperature of about 100° C. to 500° C., a vacuum pressure of about 10^{-8} to about 10^{-3} torr, and/or a deposition speed of about 0.01 to about 100 Å/s.

[0079] When the hole injection layer is formed using the spin coating method, the coating conditions may vary according to the material used to form the hole injection layer, and the structure and thermal characteristics of the hole injection

layer. For example, the coating conditions may include a coating speed of about 2,000 rpm to about 5,000 rpm, and/or a thermal treatment temperature of about 80° C. to about 200° C. at which the solvent remaining after coating may be removed.

[0080] The deposition conditions and the coating conditions of the hole injection layer may be similarly applied in forming of the hole transfer layer.

[0081] The electron transfer layer 40 may include, e.g., a quinoline derivative such as tris(8-hydroxyquinolino)aluminum (Alq3), 3-(4-biphenyl)-4-phenyl-5-(4-tert-butylphenyl)-1,2,4-triazole (TAZ), (2-methyl-8-quinolino)-4-phenylphenolate (BALq), bis(10-hydroxybenzo(h)quinolino)beryllium (Bebq2), or 4,7-diphenyl-1-10-phenanthroline (BPhen). In an implementation, lithium quinolate (Liq) may be doped to a compound selected from the group above. In an implementation, a doping density may be about 50 wt %.

[0082] The electron transfer layer 40 may have a thickness of about 100 Å to about 1,000 Å, e.g., about 200 Å to about 500 Å. Maintaining the thickness of the electron transfer layer 40 at about 100 Å or greater may help prevent a deterioration in an electron transfer characteristic. Maintaining the thickness of the electron transfer layer at about 1,000 Å or less may help prevent an increase in a driving voltage.

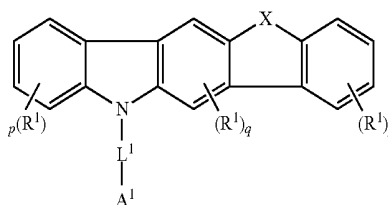
[0083] The electron transfer layer 40 may be formed using various methods, e.g., a vacuum deposition method, a spin coating method, a casting method, an LB method, or the like. The vacuum deposition method and the spin coating method may be used to form the electron transfer layer 40, and conditions thereof may be changed according to a used compound.

[0084] In addition, an electron injection layer (not shown), which may include a material that facilitates injection of electrons from a cathode, may be layered between the electron transfer layer and the cathode. The electron injection layer may include a suitable material, e.g., LiF, NaCl, CsF, Li₂O, BaO, or the like. The deposition conditions and the coating conditions of the electron injection layer may vary according to a compound that is used to form the electron injection layer. For example, the condition ranges for forming the electron injection layer may be almost the same as the conditions for forming the hole injection layer.

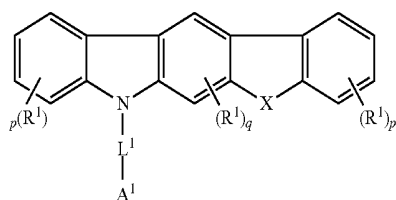
[0085] The hole blocking layer 50 according to the present exemplary embodiment may be provided between the electron transfer layer 40 and the emission layer 60. The hole blocking layer 50 may act as a barrier that blocks movement of holes. The hole blocking layer 50 may also be referred to as a buffer layer.

[0086] According to an embodiment, the hole blocking layer 50 may include a first compound represented by one of the following Chemical Formula 1-A to Chemical Formula 1-G.

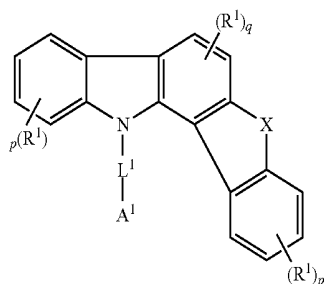
[Chemical Formula 1-A to 1-G]



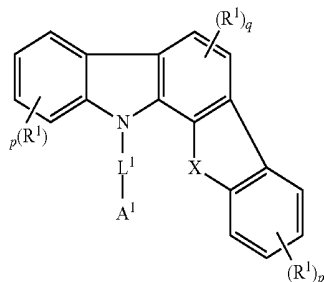
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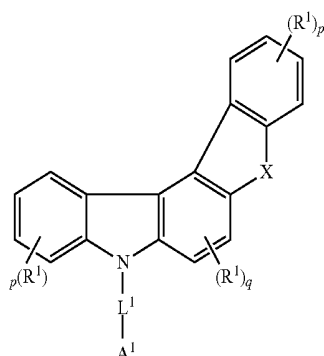
(1-B)



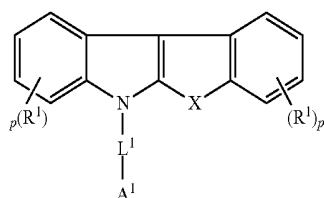
(1-C)



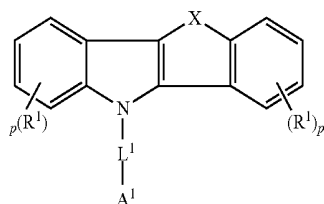
(1-D)



(1-E)



(1-F)



(1-G)

[0087] In Chemical Formula 1-A to 1-G,

[0088] A¹ may be or may include, e.g., a substituted or unsubstituted (ring-type) C6 to C30 (e.g., C6 to C30) aro-

matic hydrocarbon group or a substituted or unsubstituted (ring-type) C6 to C30 condensed aromatic heterocyclic group.

[0089] L¹ may be a connection group, and may be or include, e.g., a single bond, a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group, a substituted or unsubstituted (ring-type) C6 to C30 condensed aromatic hydrocarbon group, a substituted or unsubstituted C2 to C30 aromatic heterocyclic group, or a substituted or unsubstituted (ring-type) C2 to C30 condensed aromatic heterocyclic group.

[0090] X may be S, O, N—R¹, or C(R¹)₂,

[0091] Each R¹ may independently be or include, e.g., hydrogen (H), fluorine (F), a cyano group (—CN), a substituted or unsubstituted C1 to C20 alkyl group, a substituted or unsubstituted C1 to C20 alkoxy group, a substituted or unsubstituted C1 to C20 haloalkyl group, a substituted or unsubstituted C1 to C20 haloalkoxy group, a substituted or unsubstituted C1 to C10 alkylsilyl group, a substituted or unsubstituted C6 to C30 arylsilyl group, a substituted or unsubstituted (ring-type) C6 to C30 aromatic hydrocarbon group, a substituted or unsubstituted (ring-type) C6 to C30 condensed aromatic hydrocarbon group, a substituted or unsubstituted (ring-type) C2 to C30 aromatic heterocyclic group, or a substituted or unsubstituted C2 to C30 condensed aromatic heterocyclic group.

[0092] p may be an integer of 1 to 4,

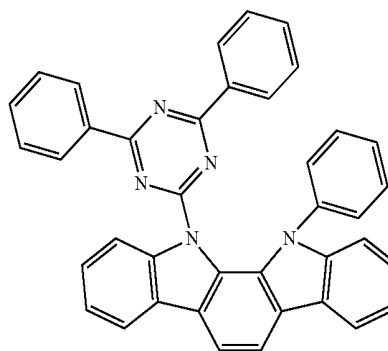
[0093] q may be an integer of 1 to 2, and

[0094] when p is an integer of 2 to 4 or q is 2, each R¹ may be the same as or different from one another.

[0095] In an implementation, the first compound may be represented by one of Chemical Formula 1-1 to Chemical Formula 1-7.

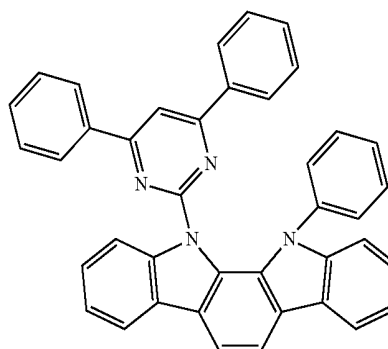
[Chemical Formula 1-1 to Chemical Formula 1-7]

(1-1)

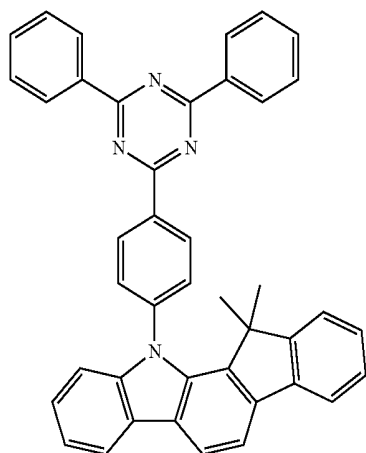


(1-F)

(1-2)

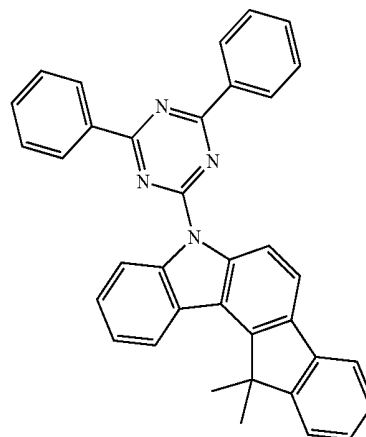


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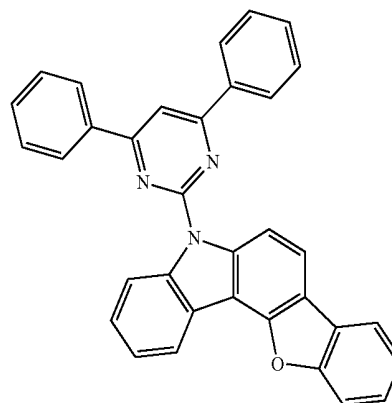
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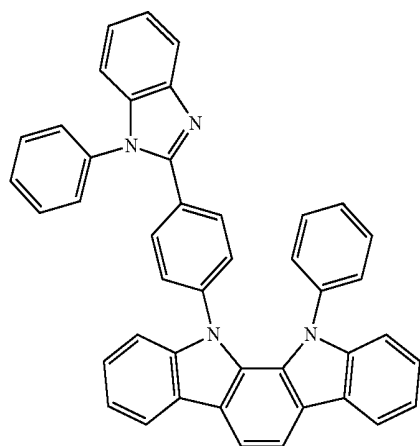


(1-6)

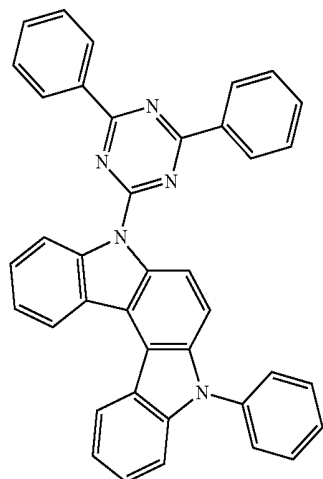
(1-7)



(1-4)



(1-5)



[0096] A thickness of the hole blocking layer 50 may be, e.g., about 10 Å to about 1,000 Å. Maintaining the thickness of the hole blocking layer 50 at about 10 Å or greater may help prevent a deterioration in hole blocking characteristics. Maintaining the thickness of the hole blocking layer 50 at about 1,000 Å or less may help prevent an increase in a driving voltage.

[0097] As described, in the organic light emitting element according to the exemplary embodiment, a carbazole-based or carbazole-containing compound (represented by Chemical Formula 1) may be used as or included in the hole blocking layer 50, and at the same time a phenyl-substituted anthracene-based or anthracene-containing compound (represented by Chemical Formula 2) may be included in the emission layer 60 of the organic light emitting element, and that carrier balance can be improved, efficiency of the organic light emitting element may be enhanced, and life span may be increased.

[0098] Next, an organic light emitting display including the organic light emitting element according to the exemplary embodiment will be described with reference to FIG. 2 to FIG. 4.

[0099] FIG. 2 illustrates a layout view of the organic light emitting display according to the exemplary embodiment. FIG. 3 illustrates a cross-sectional view of the organic light emitting display of FIG. 2, taken along the line III-III. FIG. 4 illustrates a cross-sectional view of the organic light emitting display of FIG. 2, taken along the line IV-IV.

[0100] A blocking layer **111** made of a silicon oxide or a silicon nitride may be formed on a substrate **110** made of transparent glass or the like. The blocking layer **111** may have a dual-layer structure.

[0101] A plurality of pairs of first and second semiconductor islands **151a** and **151b** may be formed on the blocking layer **111**. The first and second semiconductor islands **151a** and **151b** may be made of polysilicon or the like. Each of the semiconductor islands **151a** and **151b** may include a plurality of extrinsic regions including an n-type or p-type conductive impurity, and at least one intrinsic region that hardly may include a conductive impurity.

[0102] In the first semiconductor island **151a**, the extrinsic region may include a first source region **153a**, a first drain region **155a**, and an intermediate region **1535**, and they may be respectively doped with an n-type impurity and are separated from each other. The intrinsic region may include a pair of first channel regions **154a1** and **154a2** provided between the extrinsic regions **153a**, **1535**, and **155a**.

[0103] In the second semiconductor island **151b**, the extrinsic region may include a second source region **153b** and a second drain region **155b**, and they may be doped with a p-type impurity and are separated from each other. The intrinsic region may include a second channel region **154b** provided between the second source region **153b** and the second drain region **155b**, and a storage region **157** extended upward from the second drain region **153b**.

[0104] The extrinsic region may further include a lightly-doped region (not shown) provided between the channel regions **154a1**, **154a2**, and **154b** and the source and drain regions **153a**, **155a**, **153b**, and **155b**. Such a lightly-doped region may be replaced with an offset region that hardly includes an impurity.

[0105] In contrast, the extrinsic regions **153a** and **155a** of the first semiconductor island **151a** may be doped with the p-type impurity, or the extrinsic regions **153b** and **155b** of the second semiconductor island **151b** may be doped with the n-type impurity. The p-type conductive impurity may include boron (B), gallium (Ga), or the like, and the n-type conductive impurity may include phosphor (P), arsenic (As), or the like.

[0106] A gate insulating layer **140** made of a silicon oxide or a silicon nitride may be formed on the semiconductor islands **151a** and **151b** and the blocking layer **111**.

[0107] A plurality of gate lines **121** including a first control electrode **124a** and a plurality of gate conductors including a plurality of second control electrodes **124b** may be formed on the gate insulating layer **140**.

[0108] The gate lines **121** may transmit a gate signal and substantially extend in a horizontal direction. The first control electrode **124a** may extend upward from the gate line **121** and crosses the first semiconductor island **151a**. In this case, the first control electrode **124a** may overlap the first channel regions **154a1** and **154a2**. Each gate line **121** may include a wide end portion for connection with another layer or an external driving circuit. When a gate driving circuit generating the gate signal is integrated with the substrate **110**, the gate line **121** may be extended and thus may be directly connected with the gate driving circuit.

[0109] The second control electrode **124b** may be separated from the gate line **121** and may overlap the second channel region **154b** of the second semiconductor island **151b**. The second control electrode **124b** may form a storage electrode

127 by being extended, and the storage electrode **127** may overlap the storage region **157** of the second semiconductor island **151b**.

[0110] The gate conductors **121** and **124b** may be made of an aluminum-based metal such as aluminum (Al) or an aluminum alloy, a silver-based metal such as silver (Ag) or a silver alloy, a copper-based metal such as copper (Cu) or a copper alloy, a molybdenum-based metal such as molybdenum (Mo) or a molybdenum alloy, chromium (Cr), tantalum (Ta), or titanium (Ti). However, the gate conductors **121** and **124b** may have a multilayered structure including at least two conductive layers having different physical properties. One of the conductive layers may be made of a metal having low resistivity, e.g., an aluminum-based metal, a silver-based metal, a copper-based metal, or the like so as to reduce a signal delay or a voltage drop. In contrast, the other conductive layer may be made of another material, e.g., a material having an excellent contact characteristic with indium tin oxide (ITO) and indium zinc oxide (IZO), for example, chromium (Cr), molybdenum (Mo), a molybdenum alloy, tantalum (Ta), titanium (Ti), or the like. A combination of the two conductive layers may include a chromium lower layer and an aluminum (alloy) upper layer, or an aluminum (alloy) lower layer and a molybdenum (alloy) upper layer. However, the gate conductors **121** and **124b** may be made of various metals and conductors other than the above-stated metals and conductors.

[0111] Side surfaces of the gate conductors **121** and **124b** may be inclined with an inclination angle of about 30° to 80°.

[0112] An interlayer insulating film **160** may be formed on the gate conductors **121** and **124b**. The interlayer insulating layer **160** may be made of an inorganic insulator such as a silicon nitride or a silicon oxide, an organic insulator, a low-dielectric insulator, or the like. A dielectric constant of the low-dielectric insulator may be about 4.0 or less, and —Si: C:O, a-Si:O:F, or the like formed through plasma enhanced chemical vapor deposition (PECVD) may be examples of such a low-dielectric insulator. The interlayer insulating layer **160** may be formed of an organic insulator having photosensitivity, and the interlayer insulating layer **160** may have a flat surface.

[0113] A plurality of contact holes **164** exposing the second control electrode **124b** may be formed in the interlayer insulating layer **160**. In addition, a plurality of contact holes **163a**, **163b**, **165a**, and **165b** exposing the source and drain regions **153a**, **153b**, **155a**, and **155b** may be formed in the interlayer insulating layer **160**.

[0114] A plurality of data conductors including data lines **171**, driving voltage lines **172**, and first and second output electrodes **175a** and **175b** may be formed on the interlayer insulating layer **160**.

[0115] The data lines **171** may transmit a data signal and substantially extend in a vertical direction to cross the gate lines **121**. Each data line **171** may include a plurality of first input electrodes **173a** connected with the first source region **153a** through the contact hole **163a**, and may include a wide end portion for connection with another layer or an external driving circuit. When a data driving circuit generating the data signal is integrated with the substrate **110**, the data line **171** may be extended and then connected with the data driving circuit.

[0116] The driving voltage lines **172** may transmit a driving voltage and substantially extend in a vertical direction to cross the gate line **121**. Each of the driving voltage lines **172**

may include a plurality of second input electrodes **173b** connected with the second source region **153b** through the contact hole **163b**. The driving voltage lines **172** may overlap the storage electrode **127**, and they may be connected with each other.

[0117] The first output electrode **175a** may be separated from the data line **171** and the driving voltage line **172**. The first output electrode **175a** may be connected with the first source region **155a** through the contact hole **165a**, and may be connected with the second control electrode **124b** through the contact hole **164**.

[0118] The second output electrode **175b** may be separated from the data line **171**, the driving voltage line **172**, and the first output electrode **175a**, and may be connected with the second source **155b** through the contact hole **165b**.

[0119] The data conductors **171**, **172**, **175a**, and **175b** may be made of a refractory material such as molybdenum, chromium, tantalum, titanium, or the like, or an alloy thereof, and/or may have a multilayer structure formed of a conductive layer (not shown) such as a refractory metal or the like and a low-resistive material conductive layer (not shown). An example of the multilayered structure may include a double layer of a chromium or molybdenum (alloy) lower layer and an aluminum (alloy) upper layer, or a triple layer of a molybdenum (alloy) lower layer, an aluminum (alloy) middle layer, and a molybdenum (alloy) upper layer. However, the data conductors **171**, **172**, **175a**, and **175b** may be made of various metals and conductors other than the above-stated metals and conductors.

[0120] Like the gate conductors **121** and **121b**, the data conductors **171**, **172**, **175a**, and **175b** may also have side surfaces that are inclined preferably at about 30° to 80° with respect to the substrate **110**.

[0121] A passivation layer **180** may be formed on the data conductors **171**, **172**, **175a**, and **175b**. The passivation layer **180** may be made of an inorganic material, an organic material, a low dielectric constant insulating material, or the like.

[0122] A plurality of contact holes **185** exposing the second output electrode **175b** may be formed in the passivation layer **180**. A plurality of contact holes (not shown) exposing an end portion of the data line **171** may be formed in the passivation layer **180**, and a plurality of contact holes (not shown) exposing an end portion of the gate line **121** may be formed in the passivation layer **180** and the interlayer insulating layer **160**.

[0123] A plurality of pixel electrodes **190** may be formed on the passivation layer **180**. Each pixel electrode **190** may be physically and electrically connected with the second output electrode **175b** through the contact hole **185**, and may be made of a transparent conductive material such as ITO or IZO or a reflective metal such as aluminum, silver, or an alloy thereof.

[0124] A plurality of contact assistants (not shown) or a plurality of connecting members (not shown) may be formed on the passivation layer **180**, and they may be connected with the gate line **121** and an exposed end portion of the data line **171**.

[0125] A partition **361** may be formed on the passivation layer **180**. The partition **361** may define openings by surrounding a periphery of an edge of the pixel electrode **190** like

a bank, and may be made of an organic insulator or an inorganic insulator. The partition **361** may be made of a photoresist including a black pigment, and in this case, the partition **361** may function as a light blocking member and may be formed through a simple process.

[0126] An organic emission layer **370** may be formed on the pixel electrode **190** and a common electrode **270** may be formed on the organic emission layer **370**. In this way, an organic light emitting element including the pixel electrode **190**, the organic emission layer **370**, and the common electrode **270** may be formed.

[0127] The organic light emitting element may be the same as the above-described organic light emitting element. For example, the organic light emitting element may have a lamination structure including anode/emission layer/cathode, anode/hole transfer layer/emission layer/electron injection layer/cathode, anode/hole transfer layer/emission layer/hole blocking layer/electron transfer layer/cathode, or anode/hole transfer layer/emission layer/hole blocking layer/electron transfer layer/cathode.

[0128] In this case, the pixel electrode **190** may be an anode which is a hole injection electrode, and the common electrode **270** may become a cathode which is an electron injection electrode. In an implementation, according to a driving method of the organic light emitting device, the pixel electrode **190** may be a cathode and the common electrode **270** may be an anode. The hole and electron may be injected into the organic emission layer **370** from the pixel electrode **190** and the common electrode **270**, respectively, and an exciton generated by coupling the injected hole and electron may fall from an excited state to a ground state to emit light.

[0129] The common electrode **270** may be formed on the organic emission layer **370**. The common electrode **270** may receive a common voltage, and may be made of a reflective metal including calcium (Ca), barium (Ba), magnesium (Mg), aluminum (Al), silver (Ag), or the like, or a transparent conductive material such as ITO or IZO.

[0130] The emission layer, the hole blocking layer, and the electron injection layer may be the same as those described above. For example, the first compound, which is the carbazole-based or carbazole-containing compound, may be included as or in a hole blocking layer of the organic light emitting element, and the second compound, which is the anthracene-based or anthracene-containing compound, may be included in the emission layer, e.g., as a host.

[0131] In such an organic light emitting device, the first semiconductor island **151a**, the first control electrode **124a** connected to the gate line **121**, and the first input electrode **173a** and the first output electrode **175a** connected to the data line **171** may form a switching thin film transistor Qs, and a channel of the switching thin film transistor Qs may be formed in channel regions **154a1** and **154a2** of the first semiconductor island **151a**. The second semiconductor island **151b**, the second control electrode **124b** connected to the first output electrode **175a**, the second input electrode **173b** connected to the driving voltage line **172**, and the second output electrode **175b** connected to the pixel electrode **190** may form a driving thin film transistor Qd, and a channel of the driving thin film transistor Qd may be formed in the channel region **154b** of the second semiconductor island **151b**. The pixel

electrode **190**, the organic light emitting member **370**, and the common electrode **270** may form an organic light emitting diode, and the pixel electrode **190** may become an anode and the common electrode **270** may become a cathode, or the pixel electrode **190** may become a cathode and the common electrode **270** may become an anode. The storage electrode **127**, the driving voltage line **172**, and the storage region **157** that overlap each other may form a storage capacitor Cst.

[0132] The switching thin film transistor Qs may transmit a data signal of the data line **171** in response to a gate signal of the gate line **121**. When receiving the data signal, the driving thin film transistor Qd may flow a current that depends on a voltage difference between the second control electrode **124b** and the second input electrode **173b**. The voltage difference between the second control electrode **124b** and the second input electrode **173b** may be charged to the storage capacitor Cst and then maintained even after the switching thin film transistor Qs is turned off. The organic light emitting diode may display an image by emitting light of which the strength varies depending on a current of the driving thin film transistor Qd.

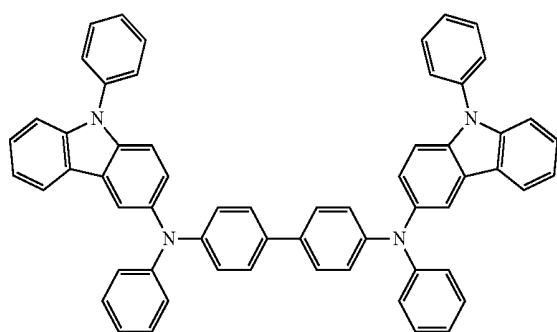
[0133] The following Examples and Comparative Examples are provided in order to highlight characteristics of one or more embodiments, but it will be understood that the Examples and Comparative Examples are not to be construed as limiting the scope of the embodiments, nor are the Comparative Examples to be construed as being outside the scope of the embodiments. Further, it will be understood that the embodiments are not limited to the particular details described in the Examples and Comparative Examples.

Example 1

[0134] An indium tin oxide (ITO) transparent electrode was formed with a thickness of 120 nm on a glass substrate. The glass substrate was then cleaned using ultrasonic waves, and a pretreatment process (i.e., UV—O₃ treatment or heat treatment) was performed.

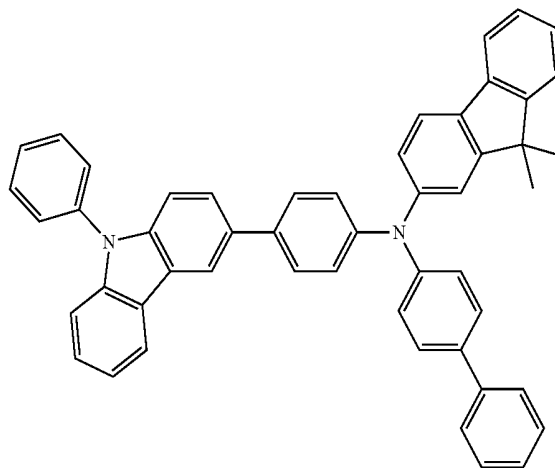
[0135] A compound represented by Chemical Formula 4 was deposited with a thickness of 50 nm as a hole injection layer on a pre-treated anode, and then a compound represented by Chemical Formula 5 was deposited with a thickness of 45 nm as a hole transfer layer thereon. Then, a compound of Chemical Formula 3, which is a doping material, was simultaneously deposited with a concentration of 5 wt % to a compound of Chemical Formula 2-1, which is a host material, such that an emission layer having a thickness of 30 nm was formed.

[Chemical Formula 4]

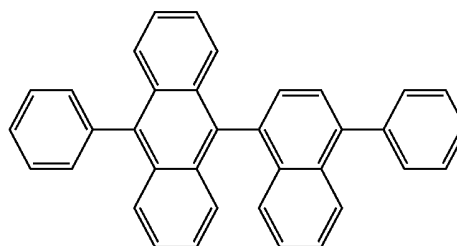


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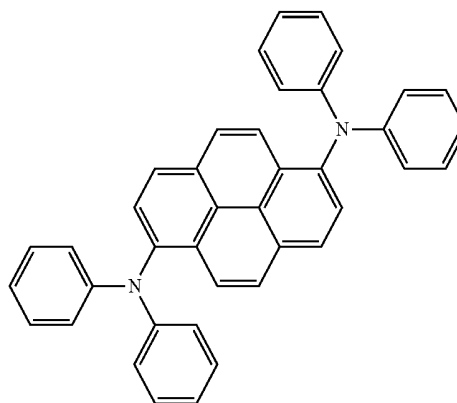
[Chemical Formula 5]



[Chemical Formula 2-1]

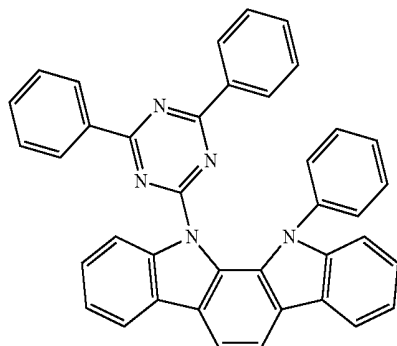


[Chemical Formula 3]



[0136] Next, as a hole blocking layer, a compound of Chemical Formula 1-1 was deposited with a thickness of 10 nm on the emission layer. Then, as an electron transfer layer, Alq was deposited with a thickness of 15 nm on the hole blocking layer. Next, as a cathode, lithium fluoride was deposited with a thickness of 0.5 nm and then aluminum was deposited with a thickness of 150 nm such that an organic light emitting element was manufactured.

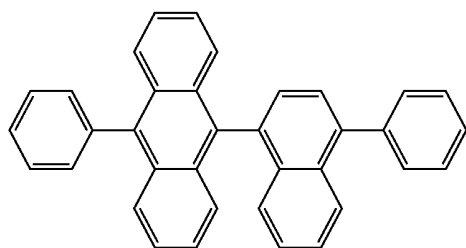
[Chemical Formula 1-1]



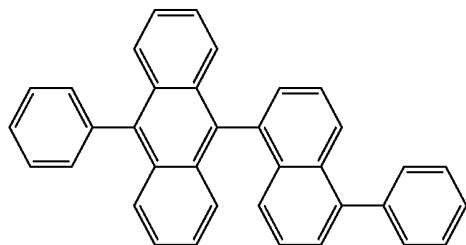
[0137] With respect to the manufactured organic light emitting element, element performance (i.e., current efficiency, Cd/A) is measured when driving with a current density of 10 mA/cm², and time (i.e., life span) until luminance is decreased to 80% from initial luminance at a current density of 50 mA/cm² was respectively measured.

[0138] The host compound of the emission layer was changed to the compounds of Chemical Formula 2-1 to Chemical Formula 2-8, respectively, and a compound of the electron blocking layer was changed to the compounds of Chemical Formula 1-1 to Chemical Formula 1-7, respectively, and then element performance and life span were measured in the same conditions.

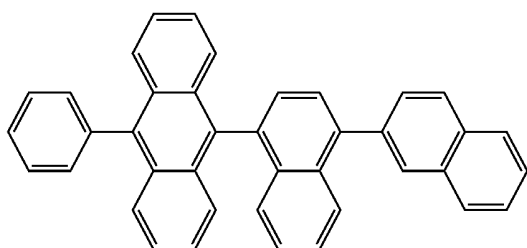
[Chemical Formula 2-1 to Chemical Formula 2-8]



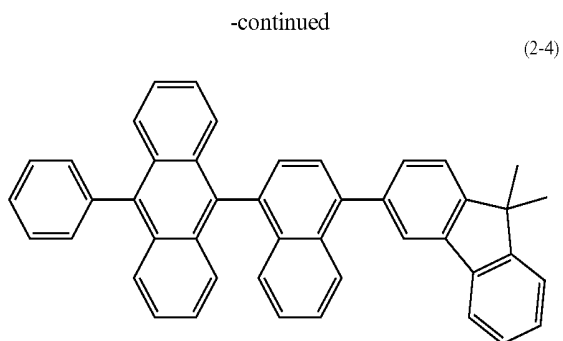
(2-1)



(2-2)

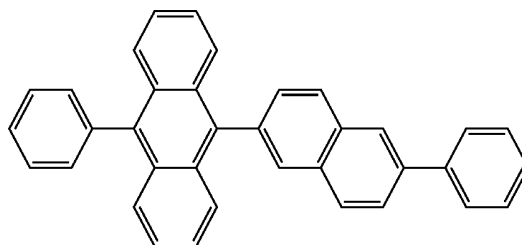


(2-3)

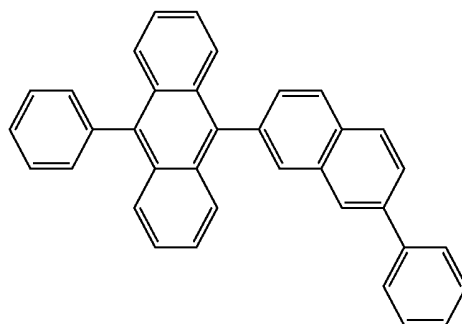


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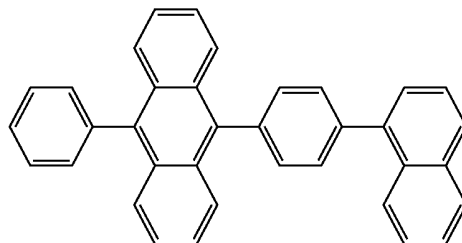
(2-4)



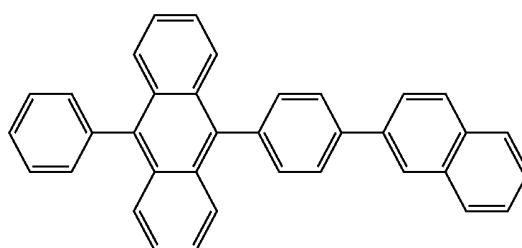
(2-5)



(2-6)



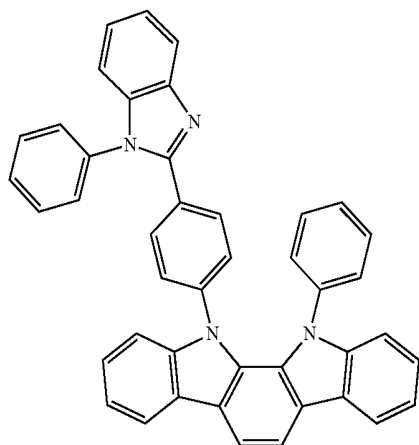
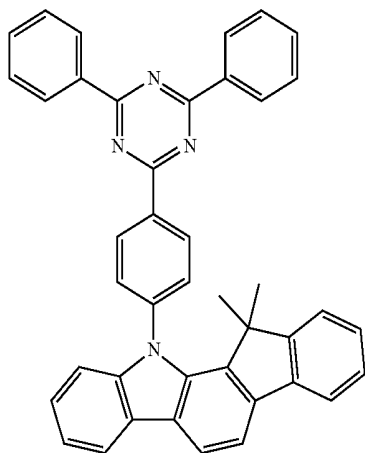
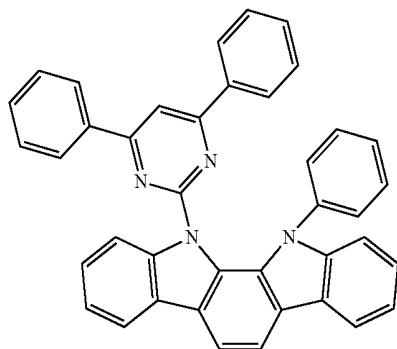
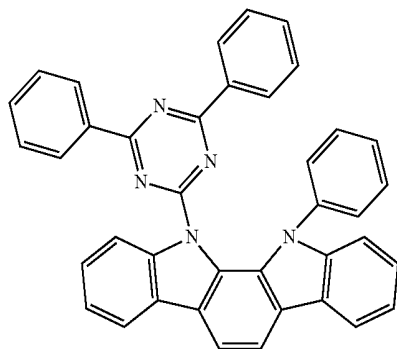
(2-7)



(2-8)

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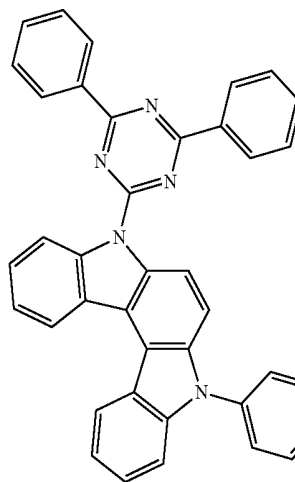
[Chemical Formula 1-1 to Chemical Formula 1-7]



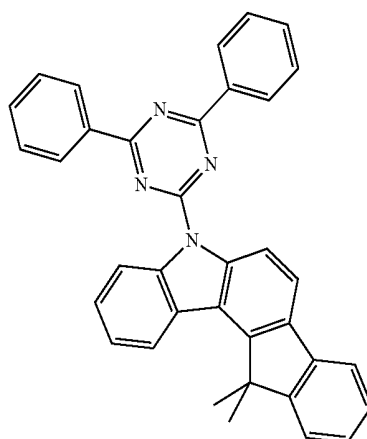
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(1-5)

(1-1)

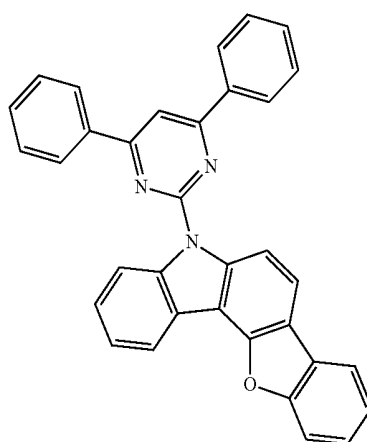


(1-2)



(1-6)

(1-3)

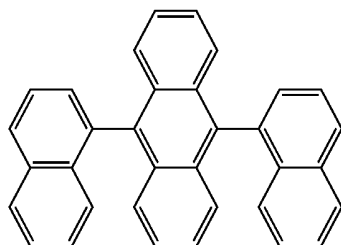


(1-7)

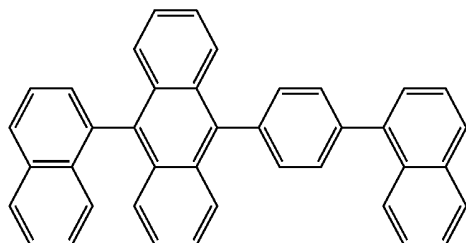
(1-4)

[0139] In addition, as Comparative Examples, an organic light emitting element was manufactured with the same conditions as of the above-described organic light emitting element of Example 1, except that a host compound was changed to compounds of Chemical Formula 6 to Chemical Formula 8.

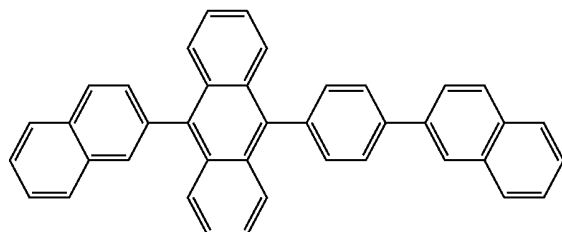
[Chemical Formula 6]



[Chemical Formula 7]



[Chemical Formula 8]



[0140] Table 1 shows measurement results.

TABLE 1

Example	Host	Hole blocking layer	Electron transfer layer	Efficiency (cd/A)	Life span (h)
Example 1-1	Chemical Formula 2-1	Chemical Formula 1-1	Alq	5.6	120
Example -2	Chemical Formula 2-1	Chemical Formula 1-2	Alq	5.5	130
Example 1-3	Chemical Formula 2-1	Chemical Formula 1-3	Alq	5.4	140
Example 1-4	Chemical Formula 2-1	Chemical Formula 1-4	Alq	5.5	120
Example 1-5	Chemical Formula 2-1	Chemical Formula 1-5	Alq	5.3	120
Example 1-6	Chemical Formula 2-1	Chemical Formula 1-6	Alq	5.5	110
Example 1-7	Chemical Formula 2-1	Chemical Formula 1-7	Alq	5.3	130

TABLE 1-continued

Example	Host	Hole blocking layer	Electron transfer layer	Efficiency (cd/A)	Life span (h)
Example 1-8	Chemical Formula 2-2	Chemical Formula 1-1	Alq	5.5	120
Example 1-9	Chemical Formula 2-3	Chemical Formula 1-1	Alq	5.6	120
Example 1-10	Chemical Formula 2-4	Chemical Formula 1-1	Alq	5.5	110
Example 1-11	Chemical Formula 2-5	Chemical Formula 1-1	Alq	5.5	120
Example 1-12	Chemical Formula 2-6	Chemical Formula 1-1	Alq	5.5	130
Example 1-13	Chemical Formula 2-7	Chemical Formula 1-1	Alq	5.4	140
Example 1-14	Chemical Formula 2-8	Chemical Formula 1-1	Alq	5.3	130
Example 1-15	Chemical Formula 2-2	Chemical Formula 1-3	Alq	5.4	130
Example 1-16	Chemical Formula 2-4	Chemical Formula 1-3	Alq	5.5	120
Example 1-17	Chemical Formula 2-5	Chemical Formula 1-3	Alq	5.4	110
Example 1-18	Chemical Formula 2-7	Chemical Formula 1-3	Alq	5.4	120
Example 1-19	Chemical Formula 2-2	Chemical Formula 1-4	Alq	5.5	120
Example 1-20	Chemical Formula 2-4	Chemical Formula 1-4	Alq	5.4	120
Example 1-21	Chemical Formula 2-5	Chemical Formula 1-4	Alq	5.5	130
Example 1-22	Chemical Formula 2-7	Chemical Formula 1-4	Alq	5.3	100
Example 1-23	Chemical Formula 2-2	Chemical Formula 1-6	Alq	5.4	110
Example 1-24	Chemical Formula 2-4	Chemical Formula 1-6	Alq	5.5	110
Example 1-25	Chemical Formula 2-5	Chemical Formula 1-6	Alq	5.4	120
Example 1-26	Chemical Formula 2-7	Chemical Formula 1-6	Alq	5.3	110
Comparative Example 1	Chemical Formula 6	Chemical Formula 1-1	Alq	4.4	50
Comparative Example 2	Chemical Formula 7	Chemical Formula 1-1	Alq	5.0	100
Comparative Example 3	Chemical Formula 8	Chemical Formula 1-1	Alq	4.9	90

Example 2

[0141] An organic light emitting element is manufactured with the same conditions of Example 1, except that 50 wt % of Liq was simultaneously deposited as a doping material to a BPhen compound to form an electron transfer layer. Efficiency and life span of the manufactured organic light emitting element are measured with the same conditions of Example 1, and measurement results are shown in Table 2.

TABLE 2

Example	Host	Hole blocking layer	Electron transfer layer	Efficiency (cd/A)	Life span (h)
Example 2-1	Chemical Formula 2-1	Chemical Formula 1-1	BPhen:Liq	5.4	130
Example 2-2	Chemical Formula 2-1	Chemical Formula 1-2	BPhen:Liq	5.4	140
Example 2-3	Chemical Formula 2-1	Chemical Formula 1-3	BPhen:Liq	5.3	150
Example 2-4	Chemical Formula 2-1	Chemical Formula 1-4	BPhen:Liq	5.4	140

TABLE 2-continued

Example	Host	Hole blocking layer	Electron transfer layer	Efficiency (cd/A)	Life span (h)
Example 2-5	Chemical Formula 2-1	Chemical Formula 1-5	BPhen:Liq	5.2	130
Example 2-6	Chemical Formula 2-1	Chemical Formula 1-6	BPhen:Liq	5.3	140
Example 2-7	Chemical Formula 2-1	Chemical Formula 1-7	BPhen:Liq	5.4	130
Example 2-8	Chemical Formula 2-2	Chemical Formula 1-1	BPhen:Liq	5.4	130
Example 2-9	Chemical Formula 2-3	Chemical Formula 1-1	BPhen:Liq	5.4	140
Example 2-10	Chemical Formula 2-4	Chemical Formula 1-1	BPhen:Liq	5.5	130
Example 2-11	Chemical Formula 2-5	Chemical Formula 1-1	BPhen:Liq	5.4	130
Example 2-12	Chemical Formula 2-6	Chemical Formula 1-1	BPhen:Liq	5.4	130
Example 2-13	Chemical Formula 2-7	Chemical Formula 1-1	BPhen:Liq	5.3	140
Example 2-14	Chemical Formula 2-8	Chemical Formula 1-1	BPhen:Liq	5.3	140
Example 2-15	Chemical Formula 2-2	Chemical Formula 1-3	BPhen:Liq	5.3	150
Example 2-16	Chemical Formula 2-4	Chemical Formula 1-3	BPhen:Liq	5.4	140
Example 2-17	Chemical Formula 2-5	Chemical Formula 1-3	BPhen:Liq	5.4	140
Example 2-18	Chemical Formula 2-7	Chemical Formula 1-3	BPhen:Liq	5.3	130
Example 2-19	Chemical Formula 2-2	Chemical Formula 1-4	BPhen:Liq	5.5	140
Example 2-20	Chemical Formula 2-4	Chemical Formula 1-4	BPhen:Liq	5.4	130
Example 2-21	Chemical Formula 2-5	Chemical Formula 1-4	BPhen:Liq	5.4	130
Example 2-22	Chemical Formula 2-7	Chemical Formula 1-4	BPhen:Liq	5.3	150
Example 2-23	Chemical Formula 2-2	Chemical Formula 1-6	BPhen:Liq	5.3	140
Example 2-24	Chemical Formula 2-4	Chemical Formula 1-6	BPhen:Liq	5.3	130
Example 2-25	Chemical Formula 2-5	Chemical Formula 1-6	BPhen:Liq	5.2	140
Example 2-26	Chemical Formula 2-7	Chemical Formula 1-6	BPhen:Liq	5.3	130
Comparative Example 4	Chemical Formula 6	Chemical Formula 1-1	BPhen:Liq	4.3	60
Comparative Example 5	Chemical Formula 7	Chemical Formula 1-1	BPhen:Liq	4.8	100
Comparative Example 6	Chemical Formula 8	Chemical Formula 1-1	BPhen:Liq	4.7	110

[0142] As shown in Table 2, it may be seen that when the compounds of Chemical Formula 1-1 to Chemical Formula 1-7 and the compounds of Chemical Formula 2 were included in a hole blocking layer and a host material, respectively, efficiency and life span were significantly improved. Referring to Table 2, even though the compounds of Chemical Formula 1-1 to Chemical Formula 1-7 were used in the hole blocking layer, efficiency and life span were improved compared to a case that the compounds of Chemical Formula 6 to Chemical Formula 8 are used as a host as in the Comparative Examples.

[0143] For example, efficiency and life span of the organic light emitting element may be improved by using a phenyl-substituted anthracene-based compound as a host and a carbazole-based compound as an electron blocking layer.

[0144] It may be seen in Table 1 and Table 2 that when the organic light emitting element is made of the above-stated

combinations, high efficiency and long life span may be acquired, regardless of the type of electron transfer layer material.

[0145] By way of summation and review, some organic light emitting devices may have a high driving voltage, high light emission brightness, low luminance and light emission efficiency, and a short life span.

[0146] The embodiments may provide an organic light emitting element having high efficiency and a long life span.

[0147] As described, the efficiency and life span of the organic light emitting element may be improved by using or including a carbazole-based or carbazole-containing compound as or in a hole blocking layer of the organic light emitting element, and a phenyl-substituted anthracene-based or containing compound as or in an emission layer of the organic light emitting element.

[0148] Example embodiments have been disclosed herein, and although specific terms are employed, they are used and are to be interpreted in a generic and descriptive sense only and not for purpose of limitation. In some instances, as would be apparent to one of ordinary skill in the art as of the filing of the present application, features, characteristics, and/or elements described in connection with a particular embodiment may be used singly or in combination with features, characteristics, and/or elements described in connection with other embodiments unless otherwise specifically indicated. Accordingly, it will be understood by those of skill in the art that various changes in form and details may be made without departing from the spirit and scope of the present invention as set forth in the following claims.

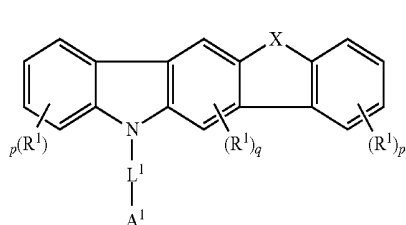
<Description of symbols>	
10: anode	20: cathode
30: hole transfer layer	40: electron transfer layer
50: electron blocking layer	60: emission layer

What is claimed is:

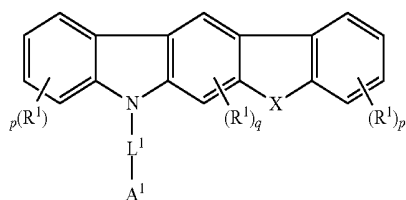
1. An organic light emitting element, comprising:

a first compound represented by one of Chemical Formula 1-A to Chemical Formula 1-G, and

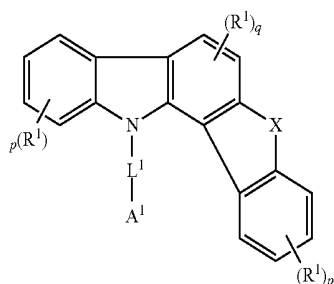
a second compound represented by Chemical Formula 2:



(1-A)

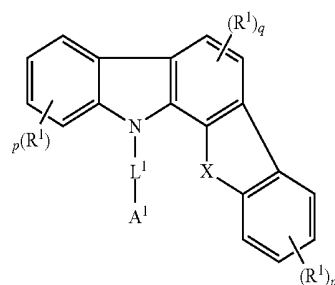


(1-B)

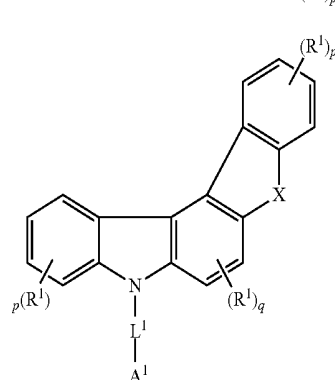


(1-C)

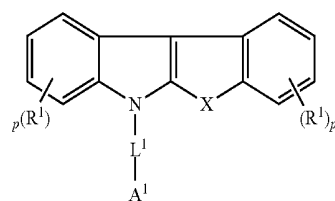
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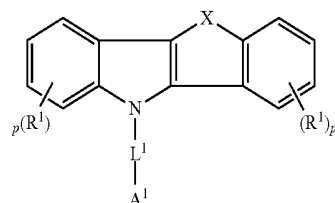
(1-D)



(1-E)



(1-F)



(1-G)

wherein, in Chemical Formula 1-A to Chemical Formula 1-G,

A¹ is a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group or a substituted or unsubstituted ring-type C6 to C30 condensed aromatic heterocyclic group,

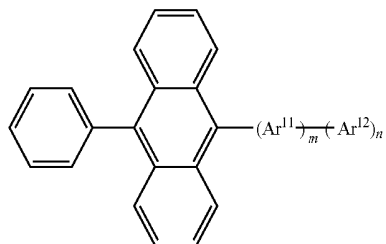
L¹ is a single bond, a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group, a substituted or unsubstituted C6 to C30 condensed aromatic hydrocarbon group, a substituted or unsubstituted C2 to C30 aromatic heterocyclic group, or a substituted or unsubstituted C2 to C30 condensed aromatic heterocyclic group,

X is S, O, N—R¹, or C(R¹)₂,

each R¹ is independently hydrogen, fluorine, a cyano group, a substituted or unsubstituted C1 to C20 alkyl group, a substituted or unsubstituted C1 to C20 alkoxy group, a substituted or unsubstituted C1 to C20 haloalkyl group, a substituted or unsubstituted C1 to C20 haloalkoxy group, a substituted or unsubstituted C1 to C10 alkylsilyl group, a substituted or unsubstituted C6 to C30 arylsilyl group, a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group, a substituted or

unsubstituted C6 to C30 condensed aromatic hydrocarbon group, a substituted or unsubstituted C2 to C30 aromatic heterocyclic group, or a substituted or unsubstituted C2 to C30 condensed aromatic heterocyclic group,
 p is an integer of 1 to 4,
 q is an integer of 1 to 2,

[Chemical Formula 2]



wherein, in Chemical Formula 2,
 each Ar¹¹ is independently a substituted or unsubstituted C5 to C30 arylene group or a substituted or unsubstituted C5 to C30 heteroarylene group,
 m is an integer of 0 to 3, such that when m is 0, Ar¹¹ is a single bond,
 each Ar¹² is independently a substituted or unsubstituted C5 to C30 aryl group or a substituted or unsubstituted C5 to C30 heteroaryl group, and
 n is an integer of 1 to 3.

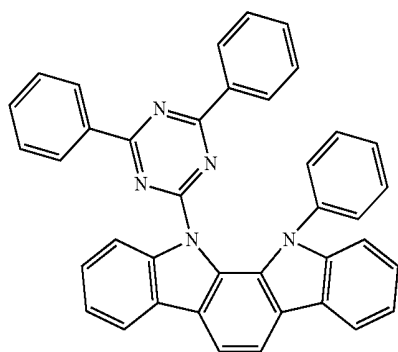
2. The organic light emitting element as claimed in claim 1, wherein:

the organic light emitting element includes:
 an anode and a cathode that face each other;
 an emission layer between the anode and the cathode;
 a hole transfer layer between the anode and the emission layer;
 an electron transfer layer between the cathode and the emission layer; and
 a hole blocking layer between the electron transfer layer and the emission layer,
 the hole blocking layer includes the first compound, and
 the emission layer includes the second compound.

3. The organic light emitting element as claimed in claim 1, wherein Ar¹¹ of the second compound includes a substituted or unsubstituted phenylene group or a substituted or unsubstituted naphthylene group.

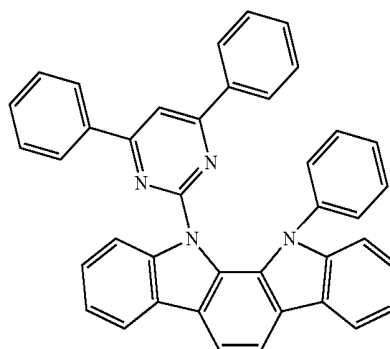
4. The organic light emitting element as claimed in claim 1, wherein the first compound is represented by one of the following Chemical Formula 1-1 to Chemical Formula 1-7:

(1-1)

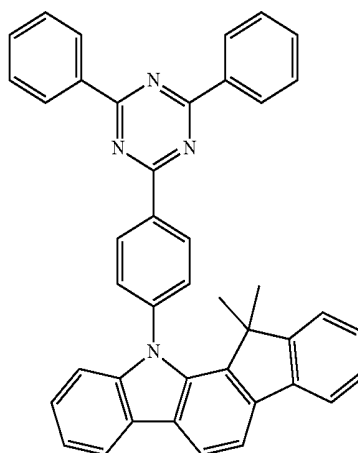


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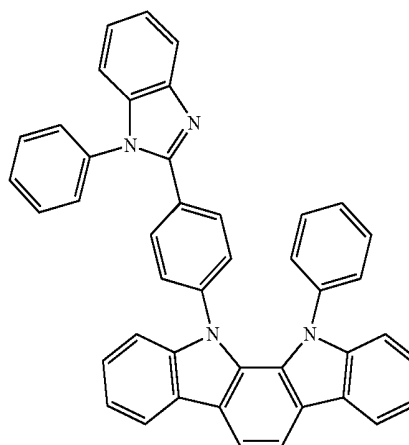
(1-2)



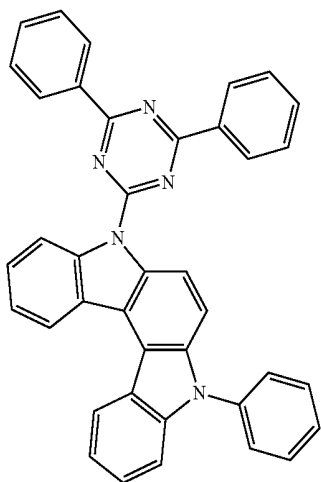
(1-3)



(1-4)



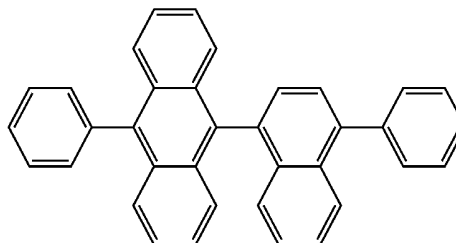
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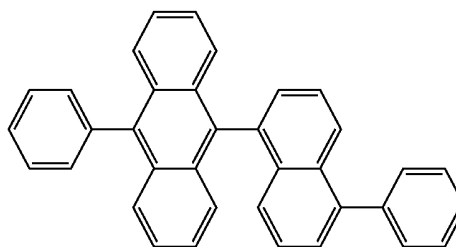
(1-5)

5. The organic light emitting element as claimed in claim 1, wherein the second compound is represented by one of the following Chemical Formula 2-1 to Chemical Formula 2-8:

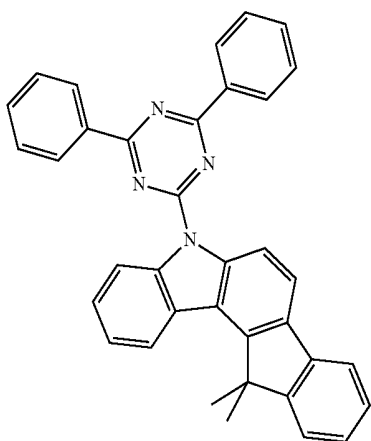
(2-1)



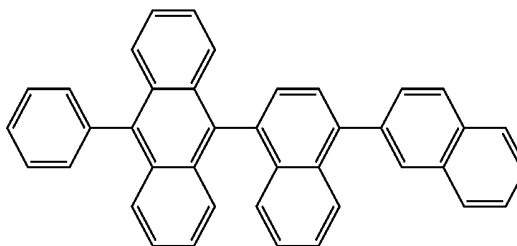
(2-2)



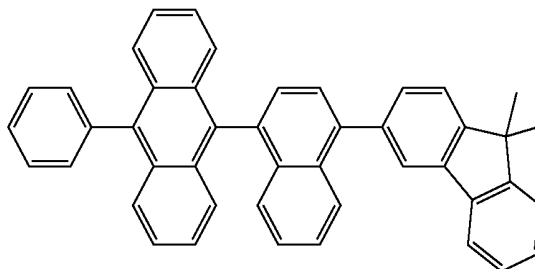
(1-6)



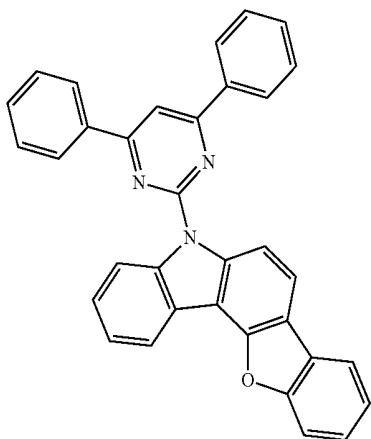
(2-3)



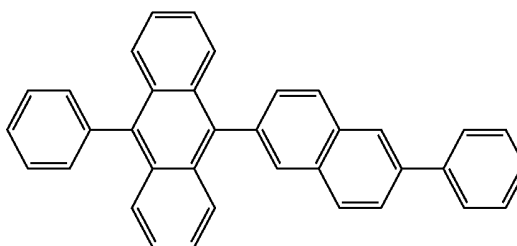
(2-4)



(1-7)

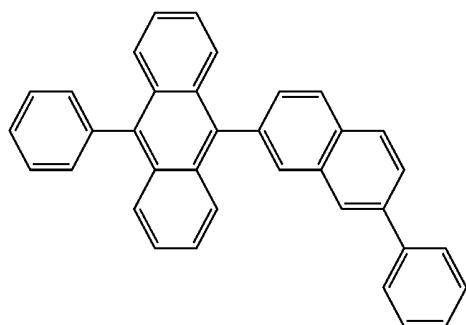


(2-5)

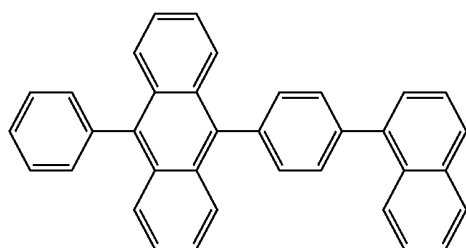


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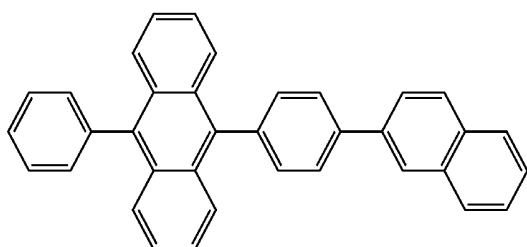
(2-6)



(2-7)



(2-8)



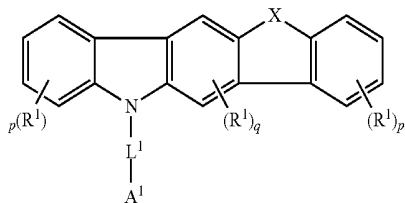
6. The organic light emitting element as claimed in claim 2, wherein the electron transfer layer includes a metal or a metal complex.

7. The organic light emitting element as claimed in claim 2, wherein the hole blocking layer has a thickness of about 1 nm to about 100 nm.

8. An organic light emitting display, comprising:

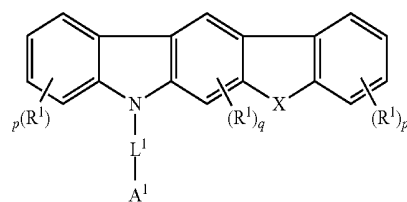
- a substrate;
 - gate lines on the substrate;
 - data lines and a driving voltage line crossing the gate lines;
 - a switching thin film transistor connected with the gate line and the data line;
 - a driving thin film transistor connected with the switching thin film transistor and the driving voltage line; and
 - an organic light emitting element connected with the driving thin film transistor,
- wherein the organic light emitting element includes:
- a first compound represented by one of Chemical Formula 1-A to Chemical Formula 1-G, and
 - a second compound represented by Chemical Formula 2:

(1-A)

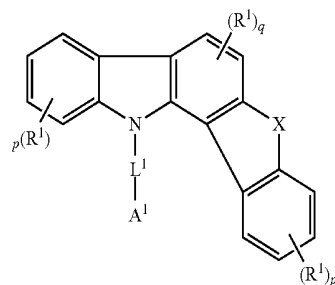


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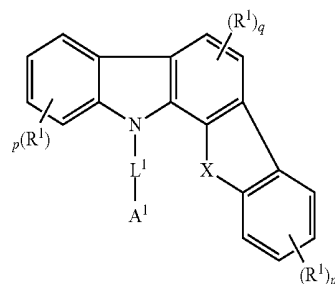
(1-B)



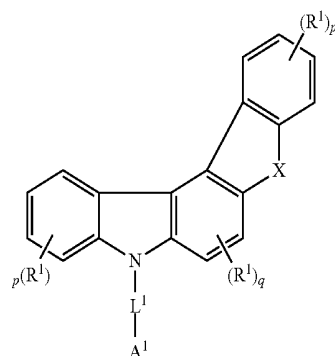
(1-C)



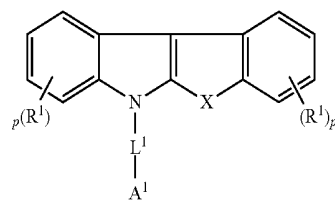
(1-D)



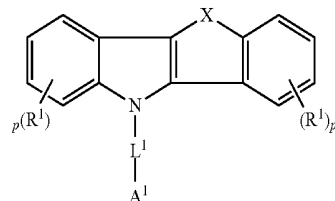
(1-E)



(1-F)



(1-G)



wherein, in Chemical Formula 1-A to Chemical Formula 1-G,

A¹ is a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group or a substituted or unsubstituted C6 to C30 condensed aromatic heterocyclic group,

L¹ is a single bond, a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group, a substituted or unsubstituted C6 to C30 condensed aromatic hydrocarbon group, a substituted or unsubstituted C2 to C30 aromatic heterocyclic group, or a substituted or unsubstituted C2 to C30 condensed aromatic heterocyclic group,

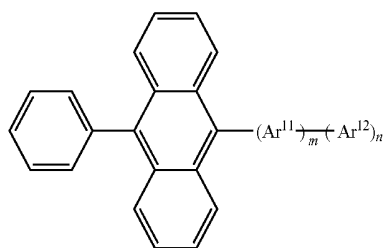
X is S, O, N—R¹, or C(R¹)₂,

each R¹ is independently, hydrogen, fluorine, a cyano group, a substituted or unsubstituted C1 to C20 alkyl group, a substituted or unsubstituted C1 to C20 alkoxy group, a substituted or unsubstituted C1 to C20 haloalkyl group, a substituted or unsubstituted C1 to C20 haloalkoxy group, a substituted or unsubstituted C1 to C10 alkylsilyl group, a substituted or unsubstituted C6 to C30 arylsilyl group, a substituted or unsubstituted C6 to C30 aromatic hydrocarbon group, a substituted or unsubstituted C6 to C30 condensed aromatic hydrocarbon group, a substituted or unsubstituted C2 to C30 aromatic heterocyclic group, or a substituted or unsubstituted C2 to C30 condensed aromatic heterocyclic group,

p is an integer of 1 to 4,

q is an integer of 1 to 2,

[Chemical Formula 2]



wherein, in Chemical Formula 2,

each Ar¹¹ is independently a substituted or unsubstituted C5 to C30 arylene group or a substituted or unsubstituted C5 to C30 heteroarylene group,

m is an integer of 0 to 3, such that when m is 0, Ar¹¹ is a single bond,

each Ar¹² is independently a substituted or unsubstituted C5 to C30 aryl group or a substituted or unsubstituted C5 to C30 heteroaryl group, and

n is an integer of 1 to 3.

9. The organic light emitting display as claimed in claim 8, wherein:

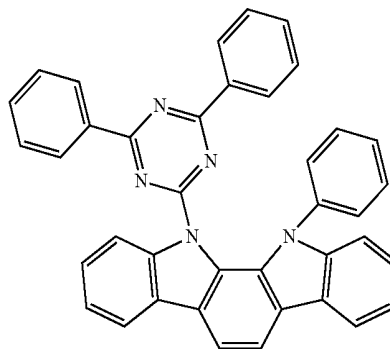
the organic light emitting element includes:
 an anode and a cathode that face each other;
 an emission layer between the anode and the cathode;
 a hole transfer layer between the anode and the emission layer;
 an electron transfer layer between the cathode and the emission layer; and
 a hole blocking layer between the electron transfer layer and the emission layer,

the hole blocking layer includes the first compound, and the emission layer includes the second compound.

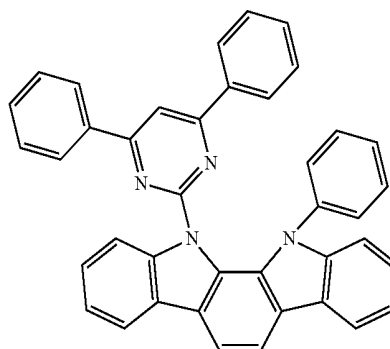
10. The organic light emitting display as claimed in claim 8, wherein Ar¹¹ of the second compound includes a substituted or unsubstituted phenylene group or a substituted or unsubstituted naphthalenylene group.

11. The organic light emitting display as claimed in claim 8, wherein the first compound is represented by one of the following Chemical Formula 1-1 to Chemical Formula 1-7:

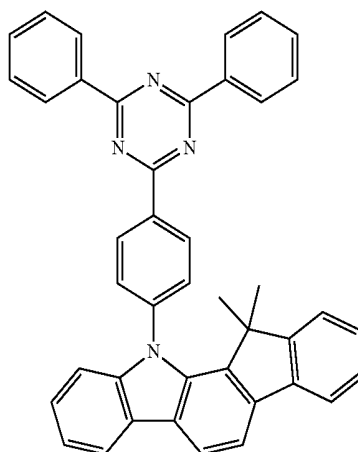
(1-1)



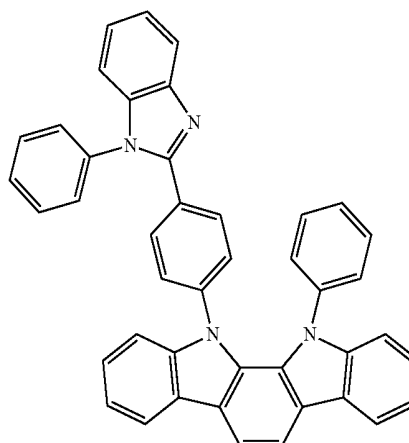
(1-2)



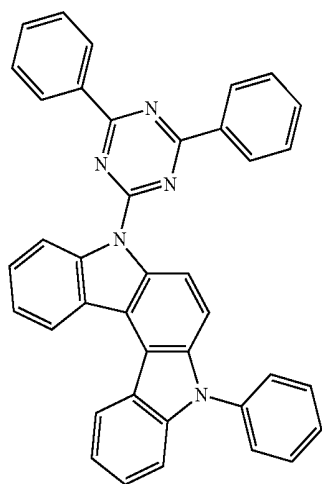
(1-3)



(1-4)



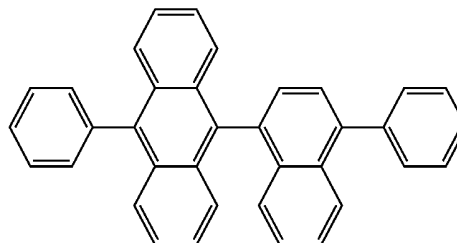
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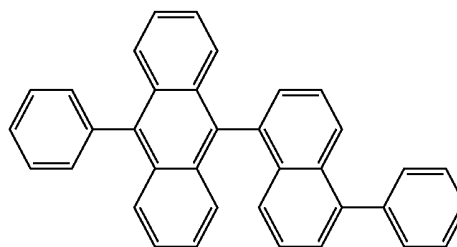
(1-5)

12. The organic light emitting display as claimed in claim 8, wherein the second compound is represented by one of the following Chemical Formula 2-1 to Chemical Formula 2-8:

(2-1)

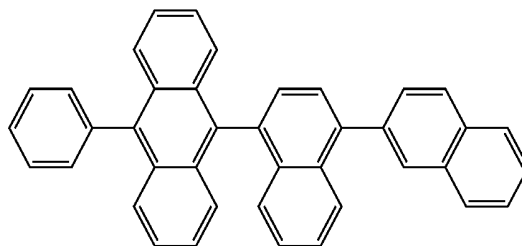


(2-2)

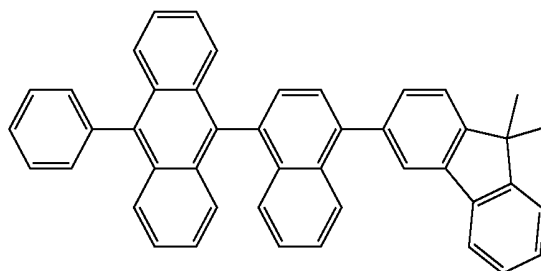


(1-6)

(2-3)

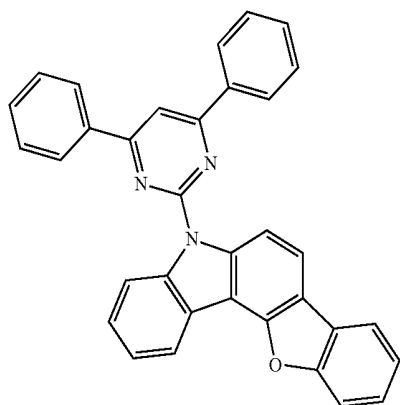
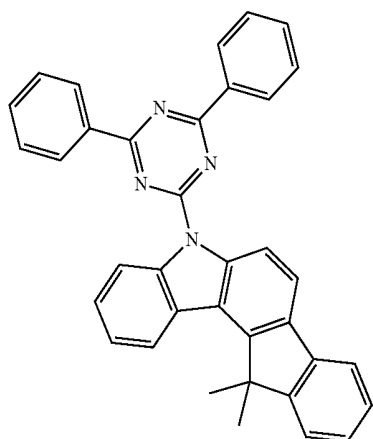
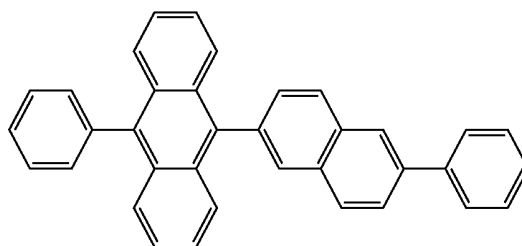


(2-4)



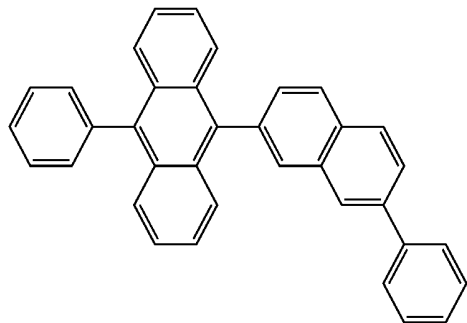
(1-7)

(2-5)

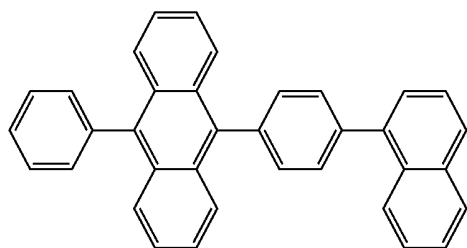


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(2-6)

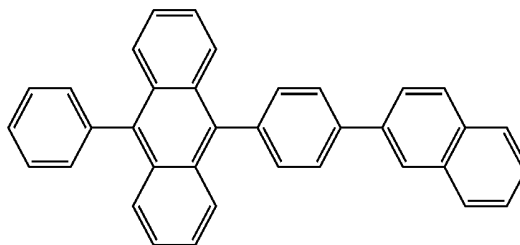


(2-7)



-continued

(2-8)



13. The organic light emitting display as claimed in claim **8**, wherein the electron transfer layer includes a metal or a metal complex.

14. The organic light emitting display as claimed in claim **8**, wherein the hole blocking layer has a thickness of about 1 nm to about 100 nm.

* * * * *

专利名称(译)	有机发光二极管和包括其的有机发光显示装置		
公开(公告)号	US20160072077A1	公开(公告)日	2016-03-10
申请号	US14/800165	申请日	2015-07-15
[标]申请(专利权)人(译)	三星显示有限公司		
申请(专利权)人(译)	三星DISPLAY CO. , LTD.		
当前申请(专利权)人(译)	三星DISPLAY CO. , LTD.		
[标]发明人	ITO NAOYUKI KIM SEUL ONG KIM YOUN SUN SHIN DONG WOO LEE JUNG SUB		
发明人	ITO, NAOYUKI KIM, SEUL ONG KIM, YOUN SUN SHIN, DONG WOO LEE, JUNG SUB		
IPC分类号	H01L51/00 C09K11/02 H01L27/32		
CPC分类号	H01L51/0072 H01L51/0081 H01L27/3276 H01L51/0058 C09K11/025 H01L2251/558 H01L51/0071 H01L51/0077 H01L51/5096 H01L51/5012 H01L51/5072 H01L51/0067		
优先权	1020140117616 2014-09-04 KR		
外部链接	Espacenet USPTO		

摘要(译)

有机发光元件和有机发光显示器，所述有机发光元件包括由化学式1-A至化学式1-G之一表示的第一化合物，和由化学式2表示的第二化合物：

